

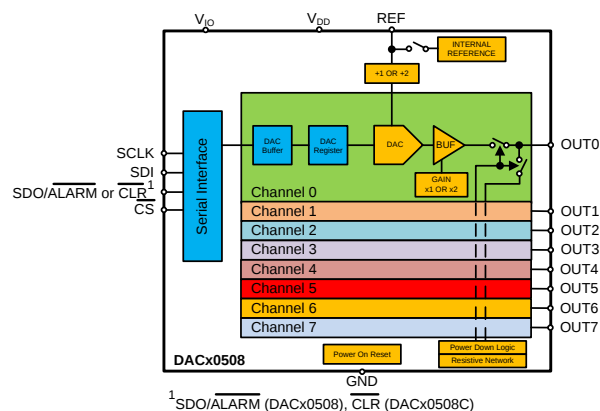


Table of Contents

1 Features	1	8.5 Programming.....	28
2 Applications	1	8.6 Register Map.....	30
3 Description	1	9 Application and Implementation	36
4 Revision History	2	9.1 Application Information.....	36
5 Device Comparison Table	4	9.2 Typical Application	38
6 Pin Configuration and Functions	5	10 Power Supply Recommendations	40
7 Specifications	6	11 Layout	41
7.1 Absolute Maximum Ratings	6	11.1 Layout Guidelines	41
7.2 ESD Ratings.....	6	11.2 Layout Examples.....	41
7.3 Recommended Operating Conditions.....	6	12 Device and Documentation Support	43
7.4 Thermal Information	7	12.1 Related Links	43
7.5 Electrical Characteristics.....	7	12.2 Receiving Notification of Documentation Updates	43
7.6 Typical Characteristics	10	12.3 Community Resources.....	43
8 Detailed Description	20	12.4 Trademarks	43
8.1 Overview	20	12.5 Electrostatic Discharge Caution.....	43
8.2 Functional Block Diagram	20	12.6 Glossary	43
8.3 Feature Description.....	21	13 Mechanical, Packaging, and Orderable	
8.4 Device Functional Modes.....	25	Information	43

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (April 2018) to Revision D	Page
• Changed TUE in Features from $\pm 0.14\%$ to 0.1%	1
• Changed Low Drift in Features from 5 ppm/°C to 2 ppm/°C and added DAC80508	1
• Added Clear Output Function: DACx0508C to Features.....	1
• Deleted 4-Wire Mode from Features	1
• Deleted 4-wire from second paragraph in Description	1
• Deleted DAC80508 Product Preview footnote from Device Information	1
• Deleted Product Preview from DAC80508Z and DAC80508M in Device Comparison Table	4
• Added DAC80508ZC and DAC80508MC to Device Comparison Table	4
• Added DAC60508ZC and DAC60508MC to Device Comparison Table	4
• Added DACx0508 to SDO/ $\overline{\text{ALARM}}$ pin description in Pin Functions	5
• Added $\overline{\text{CLR}}$ pin (DACx0508C) in Pin Functions	5
• Changed SCLK, SDI, SDO/ $\overline{\text{ALARM}}$ and $\overline{\text{CS}}$ to Digital pins for Pin voltage in Absolute Maximum Ratings	6
• Added Total unadjusted error, DAC80508. All Gains row in Electrical Characteristics	7
• Added Offset error, DAC80508. WQFN and BGA packages. All gains. row in Electrical Characteristics	7
• Added Full-scale error, DAC80508. All gains row in Electrical Characteristics	7
• Added Gain error, DAC80508 row in Electrical Characteristics	7
• Changed Short circuit current, DAC code = full scale. Output shorted to GND TYP from 35 mA to 30 mA in Electrical Characteristics	8
• Changed Short circuit current, DAC code = zero scale. Output shorted to V_{DD} TYP from 30 mA to 35 mA in Electrical Characteristics	8
• Added Channel to Channel DC crosstalk, DAC80508. Measured channel at midscale. Adjacent channel at full scale in Electrical Characteristics	8
• Added Channel to Channel DC crosstalk, DAC80508. Measured channel at midscale. All other channels at full scale in Electrical Characteristics	8
• Added Reference output drift, DAC80508 in Electrical Characteristics	9
• Added Reference thermal hysteresis, DAC80508. First cycle in Electrical Characteristics	9

Revision History (continued)

• Added SDO/ $\overline{\text{ALARM}}$ to DIGITAL OUTPUTS heading in Electrical Characteristics	9
• Deleted I_{DD} , Power-down max value in Electrical Characteristics	9
• Changed Figure 1 to Figure 18	10
• Changed Figure 20 to Figure 28	12
• Changed Figure 34	14
• Changed Figure 35	14
• Changed Figure 37	15
• Changed Figure 38	15
• Added Figure 43	16
• Added Figure 44	16
• Changed Figure 58	18
• Deleted 4-wire from paragraph in Overview section	20
• Added paragraph to Overview section	20
• Changed SDO/ $\overline{\text{ALARM}}$ to SDO/ $\overline{\text{ALARM}}$ or $\overline{\text{CLR}}$ in Functional Block Diagram	20
• Added CLEAR Operation (DACx0508C only) section	22
• Added Figure 61	23
• Deleted four-wire from Programming section	28
• Added $\overline{\text{CLR}}$ pulse in Table 7	28
• Added $\overline{\text{CLR}}$ delay and note in Table 7	28
• Changed table note for Table 8	30
• Added CLR-4TO7-MSK and CLR-0TO3-MSK bits for DACx0508C only to Figure 71	34
• Added table note to Figure 71	34
• Added CLR-4TO7-MSK and CLR-0TO3-MSK bits for DACx0508C only to Table 13	34

Changes from Revision B (January 2018) to Revision C**Page**

• Changed DAC80508Z, DAC70508Z, DAC60508Z, DAC80508M, DAC70508M, DAC60508M to DAC80508, DAC70508, DAC60508 in the data sheet header and footer	1
• Changed DAC80508Z and DAC80508M to DAC80508 in Device Information table note	1

Changes from Revision A (December 2017) to Revision B**Page**

• Added 2.4 mm x 2.4 mm, 16-Pin DSBGA to Features	1
• Added DSBGA (16) package to Device Information	1
• Added DSBGA pinout	5
• Added DSBGA package pin number column to Pin Functions table	5
• Added DSBGA package pin number column to Pin Functions table	6
• Added YZF column to Thermal Information	7
• Added Offset error test conditions and DSBGA package specific row to Electrical Characteristics	7
• Added DSBGA Layout Example	42

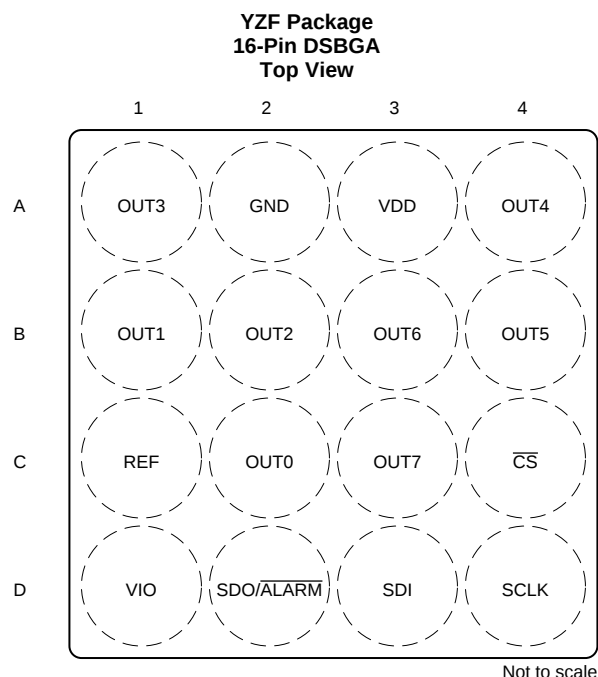
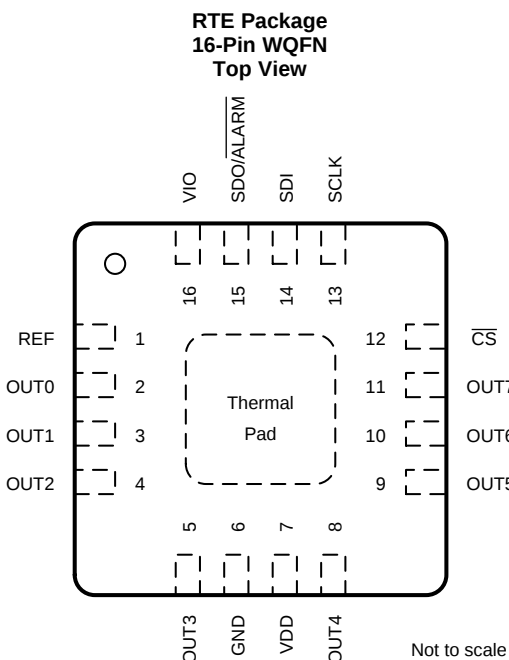
Changes from Original (June 2017) to Revision A**Page**

• Changed from Advance Information to Mixed Status	1
--	---

5 Device Comparison Table

DEVICE	RESOLUTION	REFERENCE	RESET	SDO OR $\overline{\text{CLR}}$ OPERATION
DAC80508Z	16-Bit	Internal (default) / External	Zero	SDO
DAC80508ZC				$\overline{\text{CLR}}$
DAC80508M			Midscale	SDO
DAC80508MC				$\overline{\text{CLR}}$
DAC70508Z	14-Bit	Internal (default) / External	Zero	SDO
DAC70508M			Midscale	SDO
DAC60508Z	12-Bit	Internal (default) / External	Zero	SDO
DAC60508ZC				$\overline{\text{CLR}}$
DAC60508M			Midscale	SDO
DAC60508MC				$\overline{\text{CLR}}$

6 Pin Configuration and Functions



Pin Functions

NAME	PIN		TYPE	DESCRIPTION
	WQFN NO.	DSBGA NO.		
REF	1	C1	I/O	When using internal reference, this is the reference output voltage pin (default). When using an external reference, this is the reference input pin to the device.
OUT0	2	C2	O	Analog output voltage from DAC 0.
OUT1	3	B1	O	Analog output voltage from DAC 1.
OUT2	4	B2	O	Analog output voltage from DAC 2.
OUT3	5	A1	O	Analog output voltage from DAC 3.
GND	6	A2	GND	Ground reference point for all circuitry on the device.
VDD	7	A3	PWR	Analog supply voltage (2.7 V to 5.5 V).
OUT4	8	A4	O	Analog output voltage from DAC 4.
OUT5	9	B4	O	Analog output voltage from DAC 5.
OUT6	10	B3	O	Analog output voltage from DAC 6.
OUT7	11	C3	O	Analog output voltage from DAC 7.
$\overline{\text{CS}}$	12	C4	I	Active low serial data enable. This input is the frame synchronization signal for the serial data. When the signal goes low, it enables the serial interface input shift register.
SCLK	13	D4	I	Serial interface clock.
SDI	14	D3	I	Serial interface data input. Data are clocked into the input shift register on each falling edge of the SCLK pin.
SDO/ALARM	15	D2	O	DACx0508. Serial interface data output (default). The SDO pin is in high impedance when CS pin is high. Data are clocked out of the input shift register on either rising or falling edges of the SCLK pin as specified by the FSDO bit. Alternatively the pin can be configured as an ALARM open-drain output to indicate a CRC or reference alarm event. If configured as ALARM a 10 k Ω , pull-up resistor to V _{IO} is required.
$\overline{\text{CLR}}$			I	DACx0508C. A low value on the $\overline{\text{CLR}}$ pin causes the DAC outputs of those channels configured for clear operation to update their registers and output to the reset value: zero scale (DACx0508Z) or midscale (DACx0508M). Bringing the CLR pin high causes the device to exit clear mode.

Pin Functions (continued)

PIN			TYPE	DESCRIPTION
NAME	WQFN NO.	DSBGA NO.		
VIO	16	D1	PWR	IO supply voltage (1.7 V to 5.5 V). This pin sets the I/O operating voltage for the serial interface.
Thermal Pad	–	–	–	The thermal pad is located on the bottom-side of the WQFN package. The thermal pad should be connected to any internal PCB ground plane using multiple vias for good thermal performance.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Supply voltage	V _{DD} to GND	–0.3	6	V
	V _{IO} to GND	–0.3	6	
Pin voltage	DAC outputs to GND	–0.3	V _{DD} + 0.3	V
	REF to GND	–0.3	V _{DD} + 0.3	
	Digital pins to GND	–0.3	V _{IO} + 0.3	
Input current	Input current to any pin except supply pins	–10	10	mA
Temperature	Operating free-air, T _A	–40	125	°C
	Junction, T _J	–40	150	
	Storage, T _{stg}	–60	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per JEDEC Standard 22 Test Method A114-C.01 ⁽¹⁾	±3000	V
	Charged-device model (CDM), per JEDEC Standard 22 Test Method C101, all pins ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
POWER SUPPLY						
V _{DD}	Analog supply voltage		2.7		5.5	V
V _{IO}	IO supply voltage		1.7		5.5	
DIGITAL INPUTS						
Digital input voltage			0		V _{IO}	V
REFERENCE INPUT						
V _{REFIN}	V _{DD} = 2.7 V to 3.3 V	Reference divider disabled	1.2	(V _{DD} – 0.2)/2	V	
		Reference divider enabled	2.4	V _{DD} – 0.2		
	V _{DD} = 3.3 V to 5.5 V	Reference divider disabled	1.2	V _{DD} /2		
		Reference divider enabled	2.4	V _{DD}		
TEMPERATURE						
T _A	Operating free-air temperature		–40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DACx0508		UNIT
		RTE (WQFN)	YZF (DSBGA)	
		16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	33.3	68.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	29.5	0.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	7.3	16.9	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	0.2	0.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	7.4	16.9	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	0.9	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

All minimum and maximum specifications at $V_{DD} = 2.7\text{ V to }5.5\text{ V}$, $V_{IO} = 1.7\text{ V to }5.5\text{ V}$, $V_{REFIN} = 1.25\text{ V to }5.5\text{ V}$, $R_{LOAD} = 2\text{ k}\Omega$ to GND, $C_{LOAD} = 200\text{ pF to GND}$, digital inputs at V_{IO} or GND, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC PERFORMANCE⁽¹⁾					
Resolution	DAC80508	16			Bits
	DAC70508	14			
	DAC60508	12			
INL Integral nonlinearity	DAC80508		± 0.5	± 1	LSB
	DAC70508		± 0.5	± 1	
	DAC60508		± 0.5	± 1	
DNL Differential nonlinearity	DAC80508. Specified 16-bit monotonic		± 0.5	± 1	LSB
	DAC70508. Specified 14-bit monotonic		± 0.5	± 1	
	DAC60508. Specified 12-bit monotonic		± 0.5	± 1	
TUE Total unadjusted error	DAC80508. All Gains		± 0.05	± 0.1	%FSR
	DAC70508 and DAC60508. Gain = 1 and Gain = 2		± 0.06	± 0.14	
	DAC70508 and DAC60508. Gain = $\frac{1}{2}$		± 0.1	± 0.2	
Offset error	DAC80508. WQFN and BGA packages. All gains.		± 0.75	± 1.5	mV
	DAC70508 and DAC60508. WQFN package: Gain = 1, Gain = 2 and Gain = $\frac{1}{2}$. DSBGA package: Gain = 2		± 0.75	± 1.5	
	DAC70508 and DAC60508. DSBGA package: Gain = 1 and Gain = $\frac{1}{2}$		± 0.75	± 2.5	
Zero-code error	DAC code = zero scale		0.5	1.5	mV
Full-scale error	DAC80508. All gains		± 0.05	± 0.1	% FSR
	DAC70508 and DAC60508. Gain = 1 and Gain = 2		± 0.075	± 0.14	
	DAC70508 and DAC60508. Gain = $\frac{1}{2}$		± 0.1	± 0.22	
Gain error	DAC80508		± 0.05	± 0.1	% FSR
	DAC70508 and DAC60508		± 0.05	± 0.14	
Offset error drift			± 1		$\mu\text{V}/^\circ\text{C}$
Zero-code error drift			± 2		$\mu\text{V}/^\circ\text{C}$
Full-scale error drift			± 2		ppm of FSR/ $^\circ\text{C}$
Gain error drift			± 1		ppm of FSR/ $^\circ\text{C}$
Output voltage drift over time	$T_A = 25^\circ\text{C}$, DAC code = midscale, 1600 hours		20		ppm of FSR

- (1) Static performance specified with DAC outputs unloaded for all gain options, unless otherwise noted. End point fit between codes. 16-bit: Code 256 to 65280, 14-bit: Code 128 to 16127, 12-bit: Code 16 to 4031

Electrical Characteristics (continued)

All minimum and maximum specifications at $V_{DD} = 2.7\text{ V}$ to 5.5 V , $V_{IO} = 1.7\text{ V}$ to 5.5 V , $V_{REFIN} = 1.25\text{ V}$ to 5.5 V , $R_{LOAD} = 2\text{ k}\Omega$ to GND, $C_{LOAD} = 200\text{ pF}$ to GND, digital inputs at V_{IO} or GND, $T_A = -40^\circ\text{C}$ to 125°C (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT CHARACTERISTICS					
Voltage range	Gain = 2 (BUFF-GAIN = 1, REF-DIV = 0)	0	$2 \times V_{REF}$		V
	Gain = 1 (BUFF-GAIN = 1, REF-DIV = 1)	0	V_{REF}		
	Gain = ½ (BUFF-GAIN = 0, REF-DIV = 1)	0	$\frac{1}{2} \times V_{REF}$		
Output voltage headroom	to GND or V_{DD} (unloaded)	0.004			V
	to GND or V_{DD} ($-5\text{ mA} \leq I_{OUT} \leq 5\text{ mA}$)	0.15			
	to GND or V_{DD} ($-10\text{ mA} \leq I_{OUT} \leq 10\text{ mA}$)	0.3			
	to GND or V_{DD} ($-20\text{ mA} \leq I_{OUT} \leq 20\text{ mA}$)	0.5			
Short circuit current ⁽²⁾	DAC code = full scale. Output shorted to GND	30			mA
	DAC code = zero scale. Output shorted to V_{DD}	35			
Load regulation	DAC code = midscale, $-10\text{ mA} \leq I_{OUT} \leq 10\text{ mA}$	85			µV/mA
Maximum capacitive load ⁽³⁾	$R_{LOAD} = \infty$	0	2		nF
	$R_{LOAD} = 2\text{ k}\Omega$	0	10		
DC output impedance	DAC code = midscale	0.085			Ω
	DAC output at GND or V_{DD}	15			
DYNAMIC PERFORMANCE					
Output voltage settling time	¼ to ¾ scale and ¾ to ¼ scale settling time to ±2 LSB, $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2	5			µs
Slew rate	$V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2	1.8			V/µs
Power-up time	DACx-PWDWN 1 to 0 transition. DAC code = full scale. $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2 ⁽⁴⁾	12			µs
Power-up glitch magnitude	DAC code = zero scale. $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2. $C_{LOAD} = 50\text{ pF}$	25			mV
Output noise	0.1 Hz to 10 Hz, DAC code = midscale, $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2	14			µVpp
Output noise density	1 kHz, DAC code = midscale, $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2	78			nV/√Hz
	10 kHz, DAC code = midscale, $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 2	74			
	1 kHz, DAC code = full scale, $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 1	55			
	10 kHz, DAC code = full scale, $V_{DD} = 5.5\text{ V}$, $V_{REFIN} = 2.5\text{ V}$, Gain = 1	50			
AC PSRR	DAC code = midscale, frequency = 60 Hz, amplitude = 200 mV _{PP} superimposed on V_{DD}	85			dB
DC PSRR	DAC code = midscale, $V_{DD} = 5\text{ V} \pm 10\%$	10			µV/V
Code change glitch impulse	1 LSB change around major carrier	4			nV-s
Channel to Channel AC crosstalk	DAC code = midscale. Code 32 to full-scale swing on adjacent channel	0.2			nV-s
Channel to Channel DC crosstalk	DAC80508. Measured channel at midscale. Adjacent channel at full scale	5			µV
	DAC70508 and DAC60508. Measured channel at midscale. Adjacent channel at full scale	10			
	DAC80508. Measured channel at midscale. All other channels at full scale	10			
	DAC70508 and DAC60508. Measured channel at midscale. All other channels at full scale	80			
Digital feedthrough	DAC code = midscale. $f_{SCLK} = 1\text{ MHz}$, SDO disabled	0.1			nV-s
EXTERNAL REFERENCE INPUT					
Reference input current	$V_{REFIN} = 2.5\text{ V}$	25			µA
Reference input impedance		100			kΩ
Reference input capacitance		5			pF

(2) Temporary overload condition protection. Junction temperature can be exceeded during current limit. Operation above the specified maximum junction temperature may impair device reliability.

(3) Specified by design and characterization. Not tested during production.

(4) Time to exit DAC power-down mode. Measured from $\overline{\text{CS}}$ rising edge to 90% of DAC final value.

Electrical Characteristics (continued)

All minimum and maximum specifications at $V_{DD} = 2.7\text{ V to }5.5\text{ V}$, $V_{IO} = 1.7\text{ V to }5.5\text{ V}$, $V_{REFIN} = 1.25\text{ V to }5.5\text{ V}$, $R_{LOAD} = 2\text{ k}\Omega$ to GND, $C_{LOAD} = 200\text{ pF to GND}$, digital inputs at V_{IO} or GND, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INTERNAL REFERENCE						
Reference output voltage, V_{REFOUT}		$T_A = 25^{\circ}\text{C}$	2.495	2.5	2.505	V
Reference output drift		DAC80508		2	5	ppm/ $^{\circ}\text{C}$
		DAC70508 and DAC60508		5	8	
Reference output impedance				0.1		Ω
Reference output noise		0.1 Hz to 10 Hz		15		μVpp
Reference output noise density		10 kHz, $\text{REF}_{\text{LOAD}} = 10\text{ nF}$		130		$\text{nV}/\sqrt{\text{Hz}}$
Reference load current				± 5		mA
Reference load regulation		Source and sink		100		$\mu\text{V}/\text{mA}$
Reference line regulation				20		$\mu\text{V}/\text{V}$
Reference output drift over time		$T_A = 25^{\circ}\text{C}$, 1600 hours		4.8		ppm
Reference thermal hysteresis		DAC80508. First cycle		50		ppm
		DAC70508 and DAC60508. First cycle		190		
		Additional cycle		18		
DIGITAL INPUTS						
V_{IH}	High-level input voltage		$0.7 \times V_{\text{IO}}$			V
V_{IL}	Low-level input voltage		$0.3 \times V_{\text{IO}}$			V
Input current				± 2		μA
Input pin capacitance				2		pF
DIGITAL OUTPUTS: SDO/ALARM						
V_{OH}	High-level output voltage	$I_{\text{LOAD}} = 0.2\text{ mA}$	$V_{\text{IO}} - 0.4$			V
V_{OL}	Low-level output voltage	$I_{\text{LOAD}} = -0.2\text{ mA}$	0.4			V
Output pin capacitance				4		pF
POWER SUPPLY REQUIREMENTS						
I_{DD}	V_{DD} supply current	Active mode. Internal reference enabled. Gain = 1. DAC code = full scale. Outputs unloaded. SPI static		5	6	mA
		Active mode. Internal reference disabled. Gain = 1. DAC code = full scale. Outputs unloaded. SPI static		4.5	5.5	
			Power-down		15	
I_{IO}	V_{IO} supply current			2	3	μA

7.6 Typical Characteristics

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V, Gain = 2, DAC outputs unloaded, unless otherwise noted.

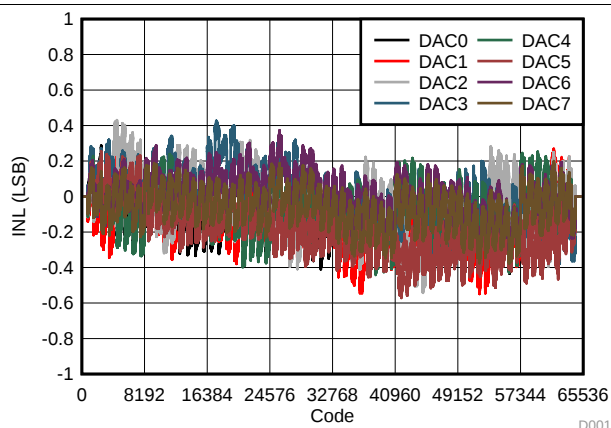


Figure 1. Integral Linearity Error vs Digital Input Code

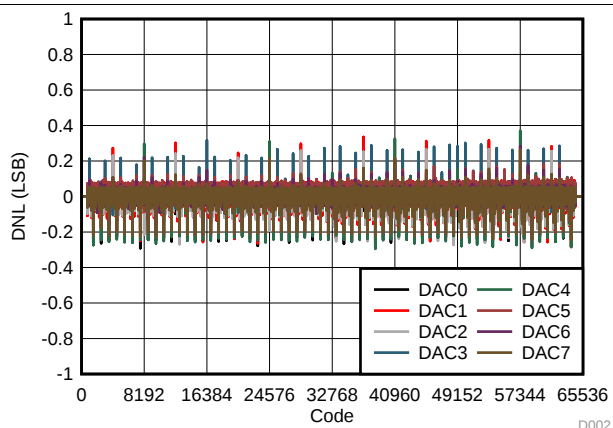


Figure 2. Differential Linearity Error vs Digital Input Code

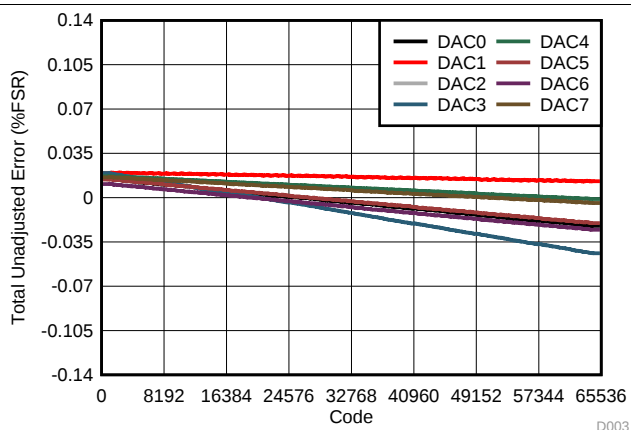


Figure 3. Total Unadjusted Error vs Digital Input Code

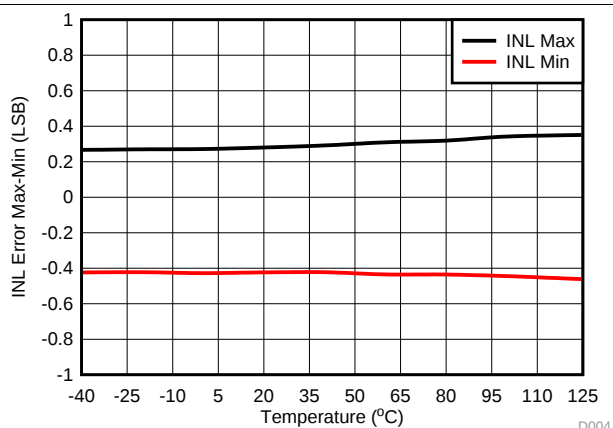


Figure 4. Integral Linearity Error vs Temperature

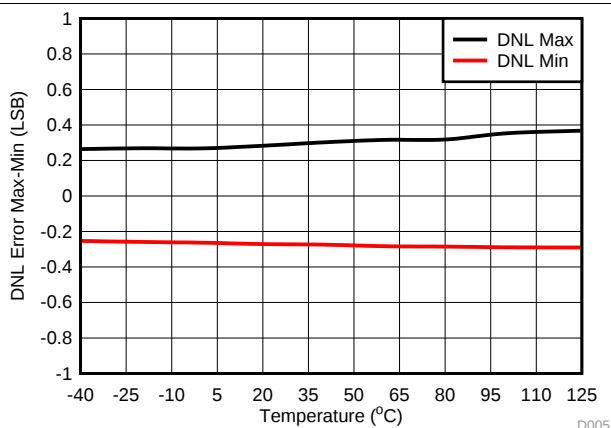


Figure 5. Differential Linearity Error vs Temperature

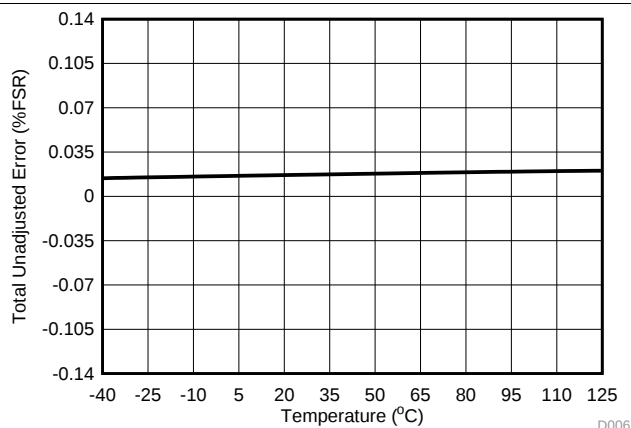


Figure 6. Total Unadjusted Error vs Temperature

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.

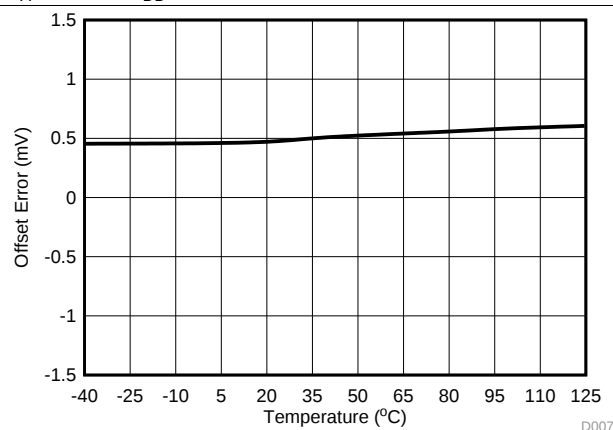


Figure 7. Offset Error vs Temperature

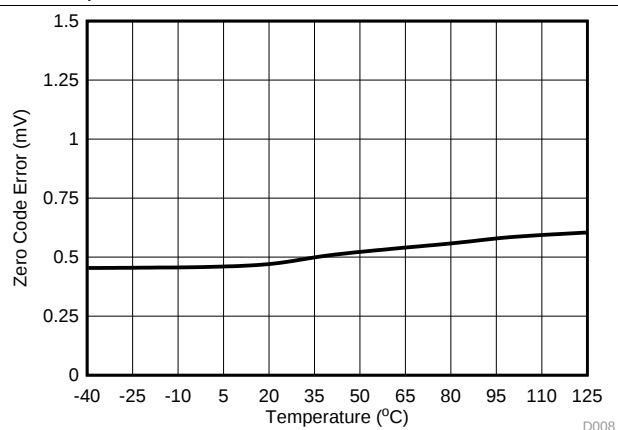


Figure 8. Zero Code Error vs Temperature

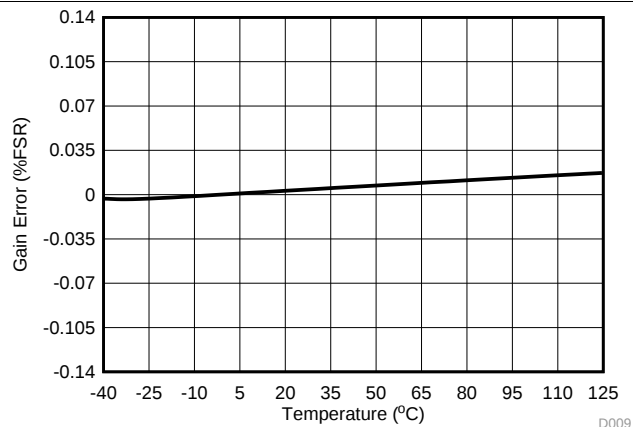


Figure 9. Gain Error vs Temperature

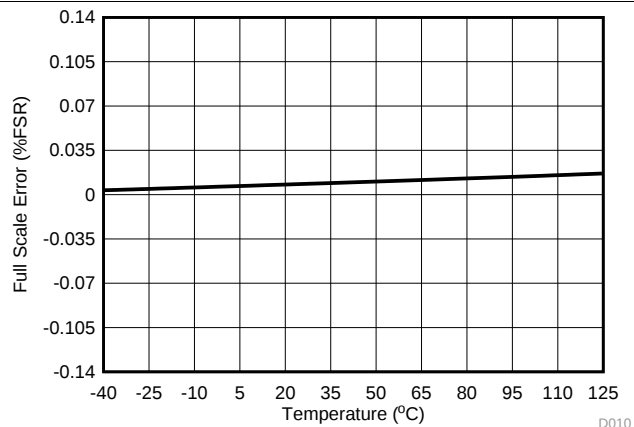
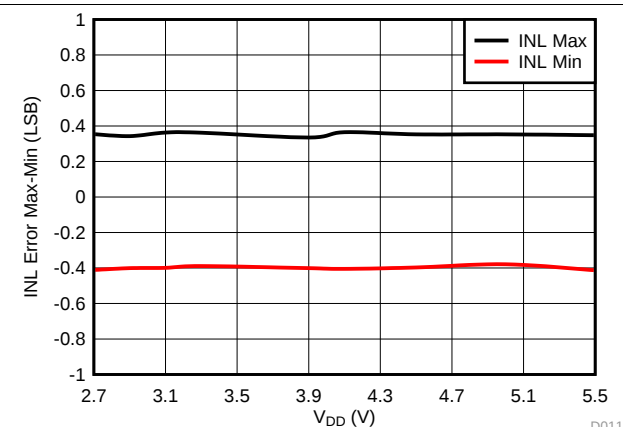
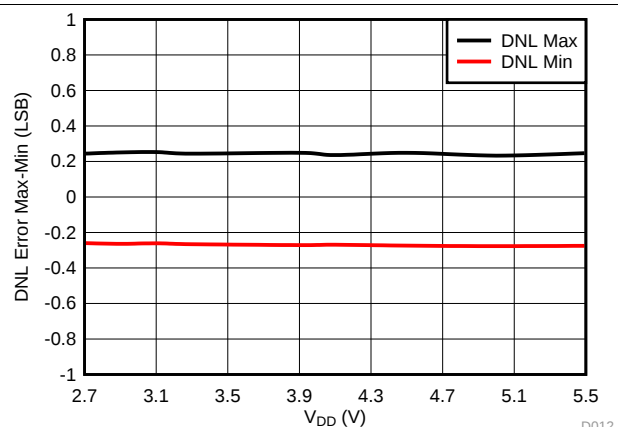


Figure 10. Full Scale Error vs Temperature



Gain = 1

Figure 11. Integral Linearity Error vs Supply Voltage



Gain = 1

Figure 12. Differential Linearity Error vs Supply Voltage

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.

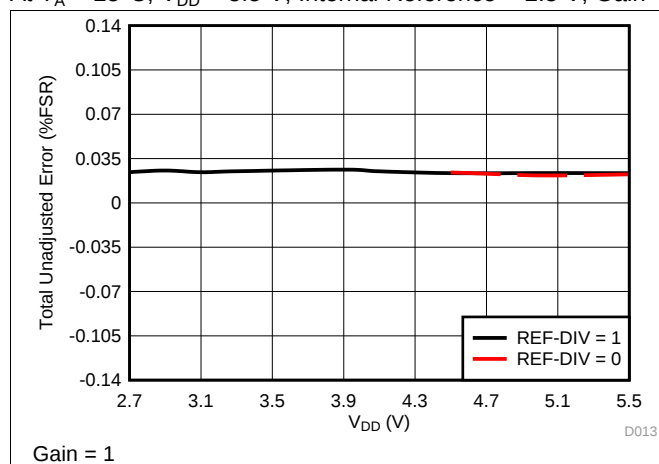


Figure 13. Total Unadjusted Error vs Supply Voltage

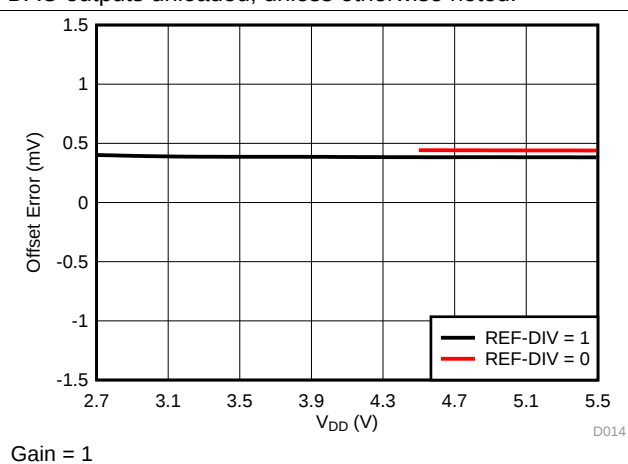


Figure 14. Offset Error vs Supply Voltage

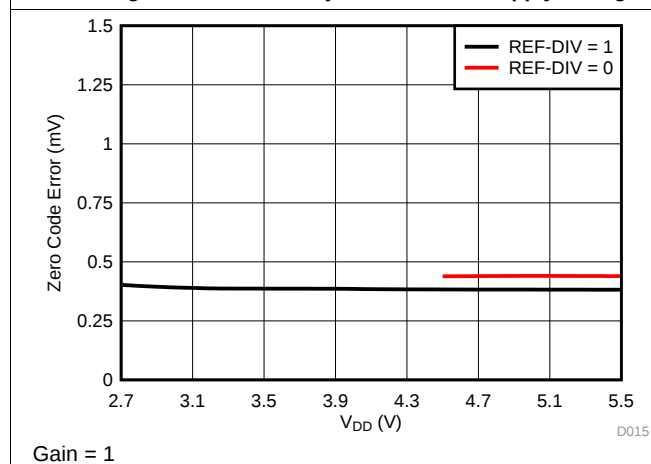


Figure 15. Zero Code Error vs Supply Voltage

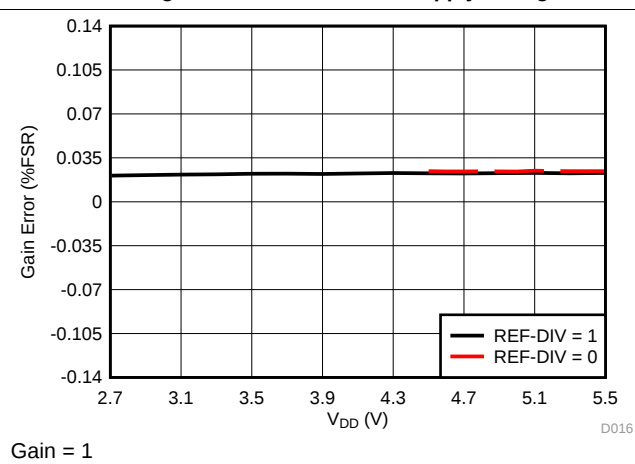


Figure 16. Gain Error vs Supply Voltage

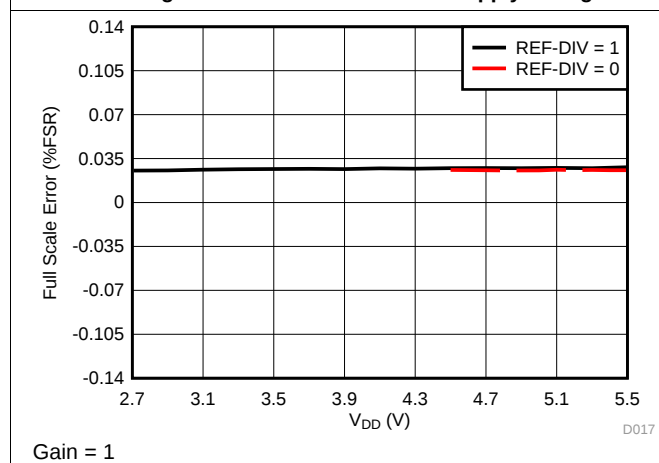


Figure 17. Full Scale Error vs Supply Voltage

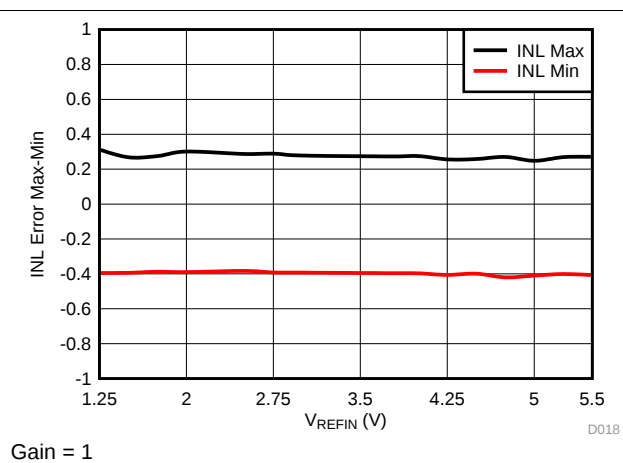
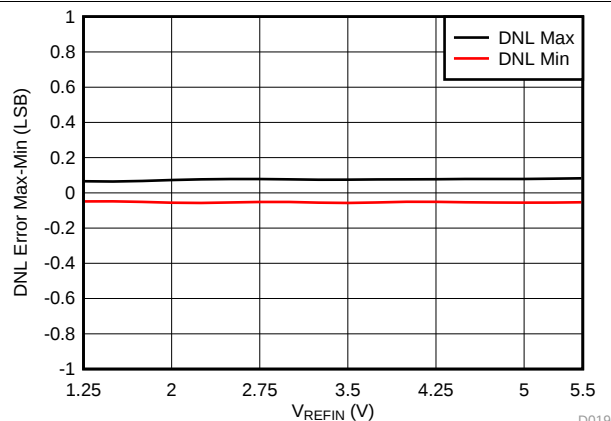


Figure 18. Integral Linearity Error vs Reference Voltage

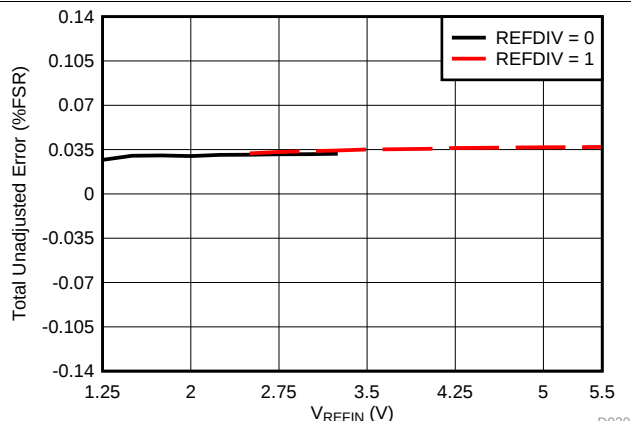
Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.



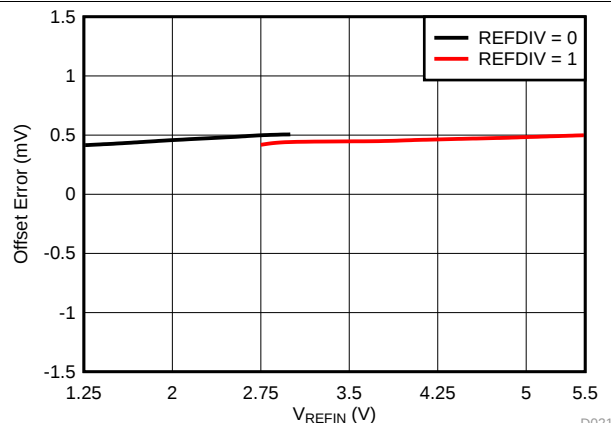
Gain = 1

Figure 19. Differential Linearity Error vs Reference Voltage



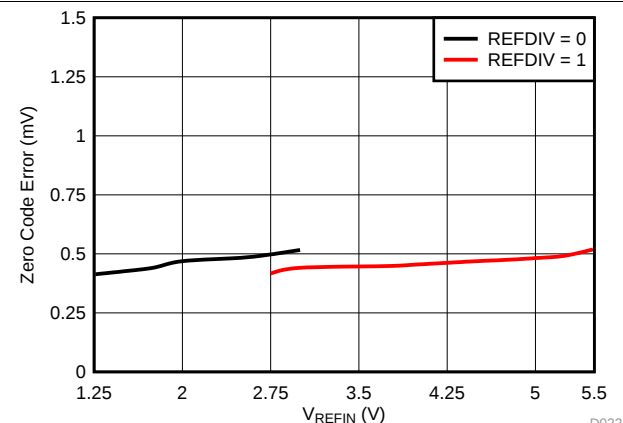
Gain = 1

Figure 20. Total Unadjusted Error vs Reference Voltage



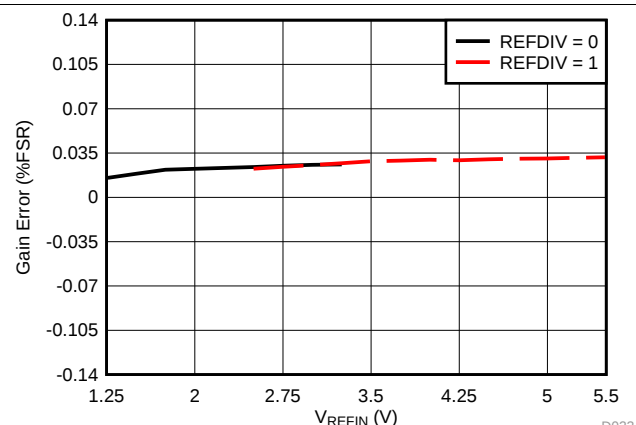
Gain = 1

Figure 21. Offset Error vs Reference Voltage



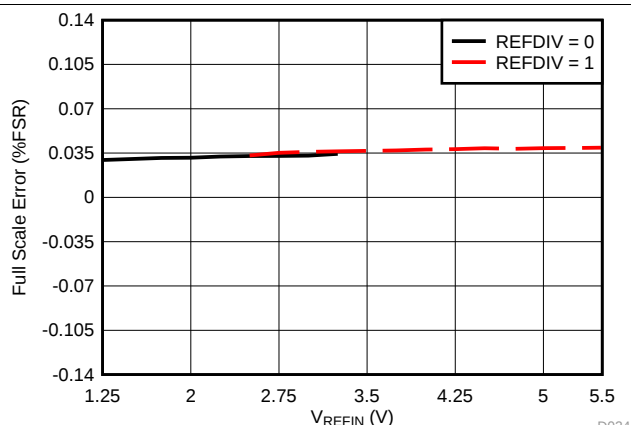
Gain = 1

Figure 22. Zero Code Error vs Reference Voltage



Gain = 1

Figure 23. Gain Error vs Reference Voltage

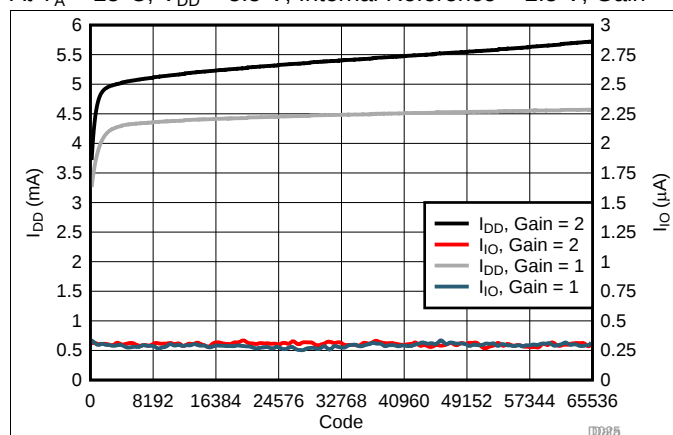


Gain = 1

Figure 24. Full Scale Error vs Reference Voltage

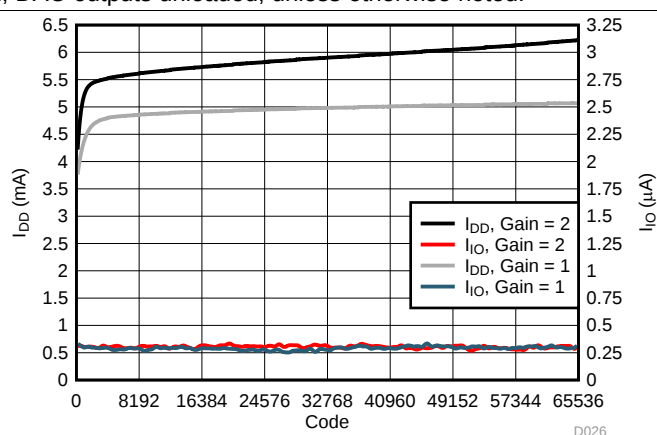
Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.



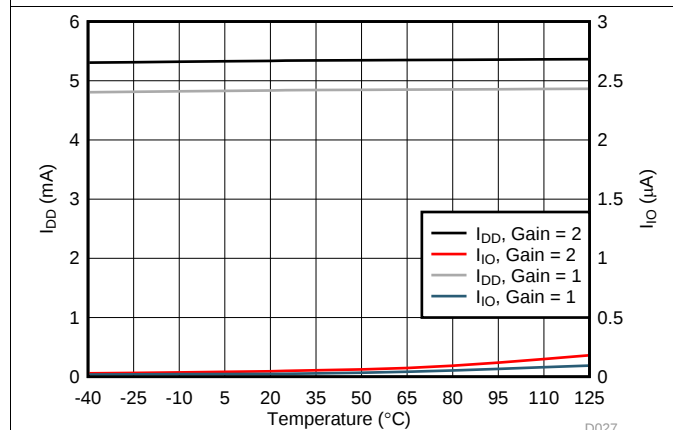
Gain = 1. External Reference = 2.5 V

Figure 25. Supply Current with External Reference vs Digital Input Code



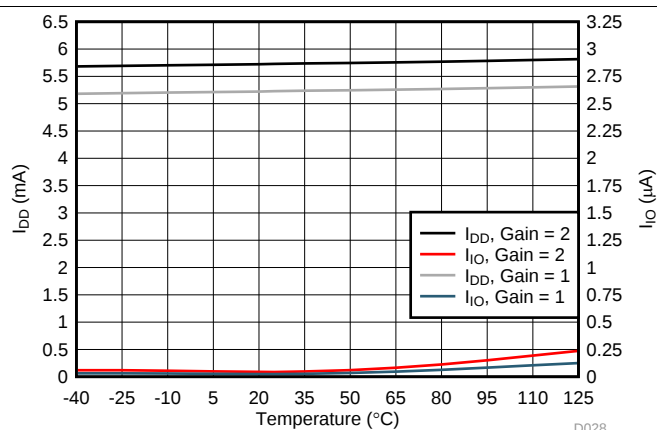
Gain = 1

Figure 26. Supply Current with Internal Reference vs Digital Input Code



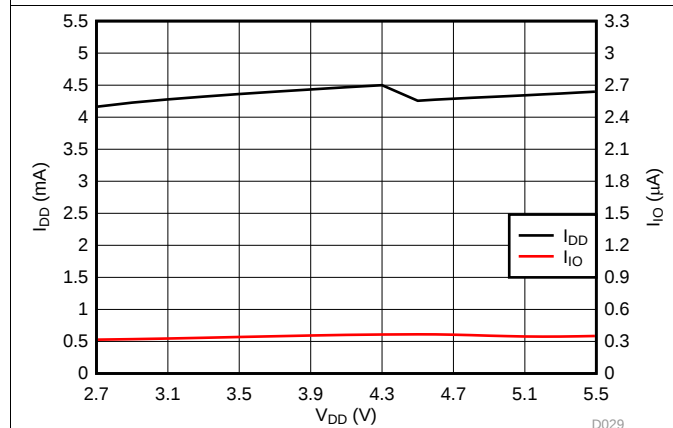
Gain = 1. External Reference = 2.5 V

Figure 27. Supply Current with External Reference vs Temperature



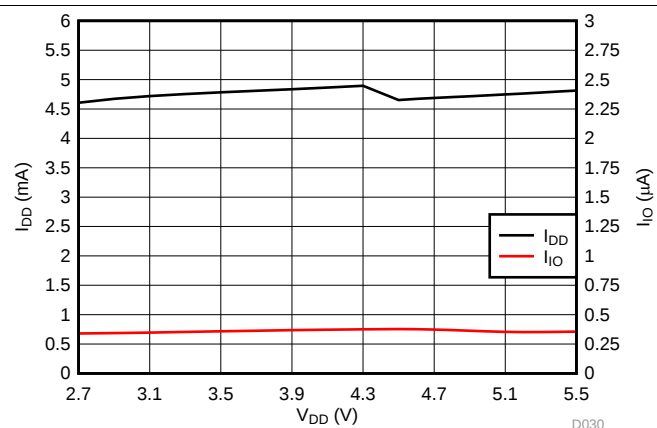
Gain = 1

Figure 28. Supply Current with Internal Reference vs Temperature



Gain = 1. External Reference = 2.5 V

Figure 29. Supply Current with External Reference vs Supply Voltage



Gain = 1

Figure 30. Supply Current with Internal Reference vs Supply Voltage

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.

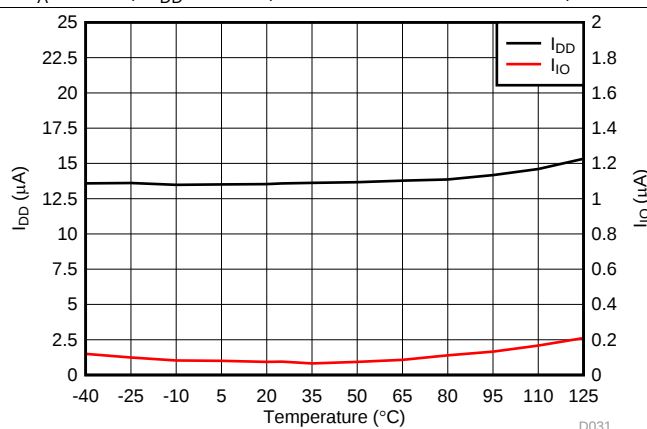


Figure 31. Power Down Current vs Temperature

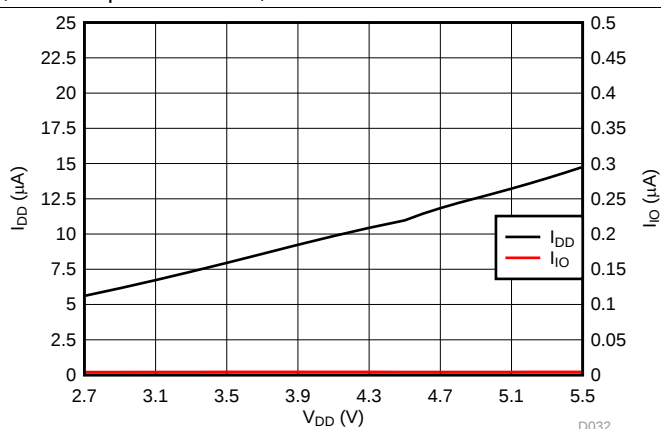


Figure 32. Power Down Current vs Supply Voltage

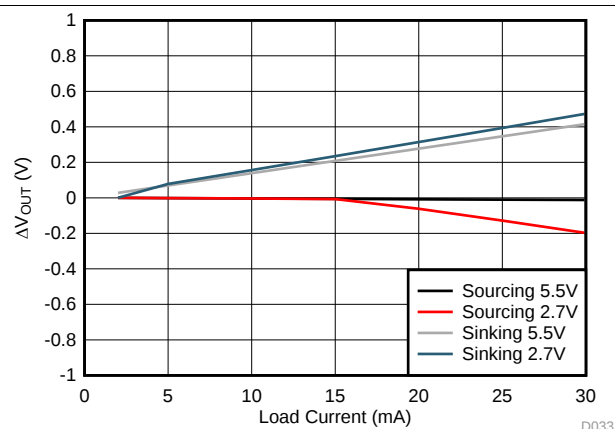


Figure 33. Headroom/Footroom vs Load Current

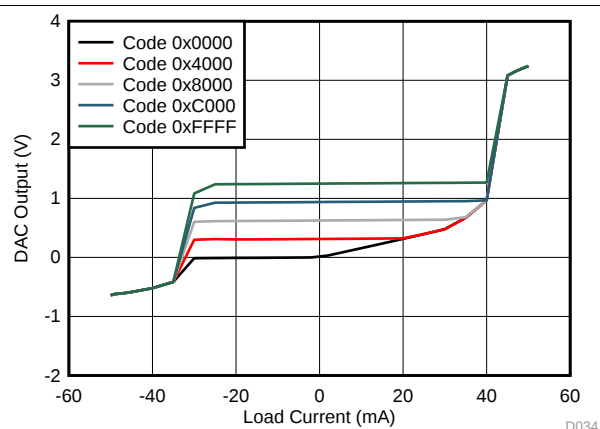


Figure 34. Source and Sink Capability with Gain = $\frac{1}{2}$

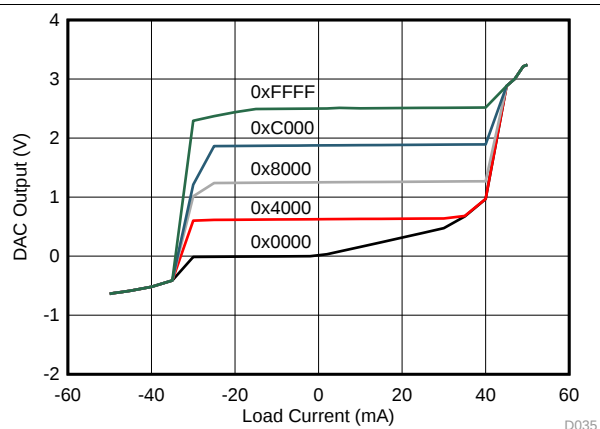


Figure 35. Source and Sink Capability with Gain = 1

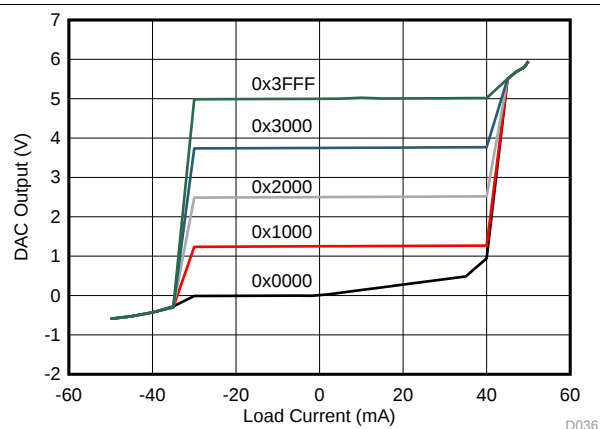
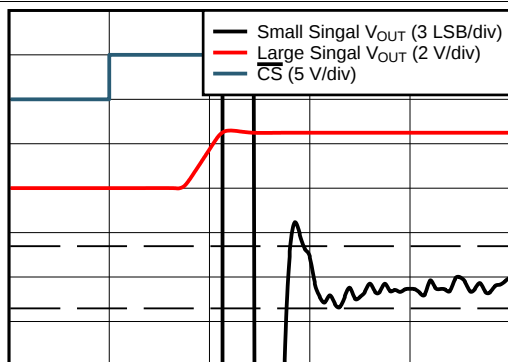


Figure 36. Source and Sink Capability with Gain = 2

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.

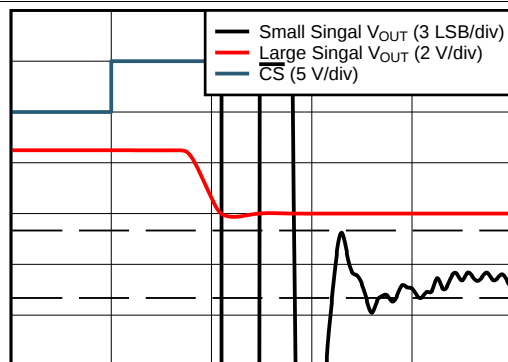


Time (2 μsec/div)

Gain = 1

D037

Figure 37. Full-Scale Settling Time, Rising Edge

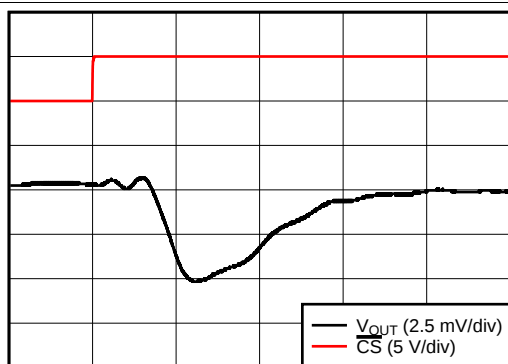


Time (2 μsec/div)

Gain = 1

D038

Figure 38. Full-Scale Settling Time, Falling Edge

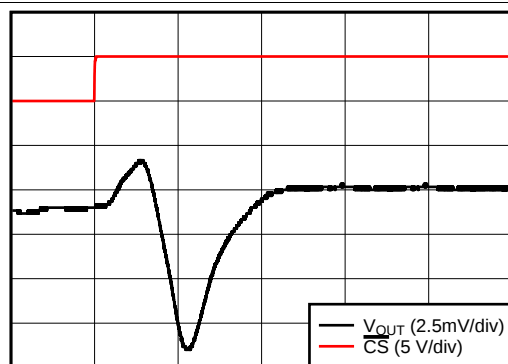


Time (0.5 μs/div)

Gain = 1

D039

Figure 39. Glitch Impulse, Falling Edge, 1 LSB Step

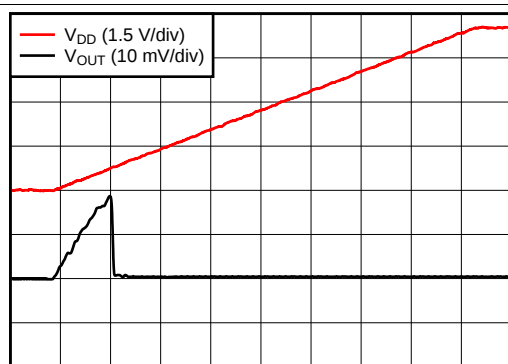


Time (0.5 μs/div)

Gain = 1

D040

Figure 40. Glitch Impulse, Rising Edge, 1 LSB Step

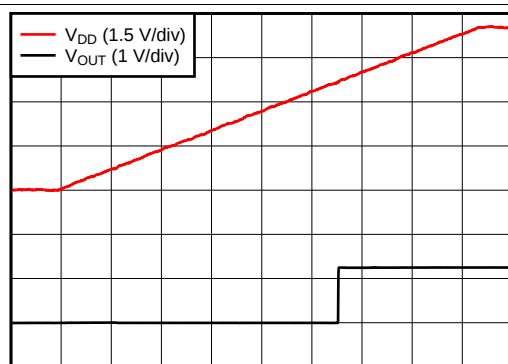


Time (600 μs/div)

Gain = 1

D041

Figure 41. Power-On, Reset to Zero Scale



Time (600 μs/div)

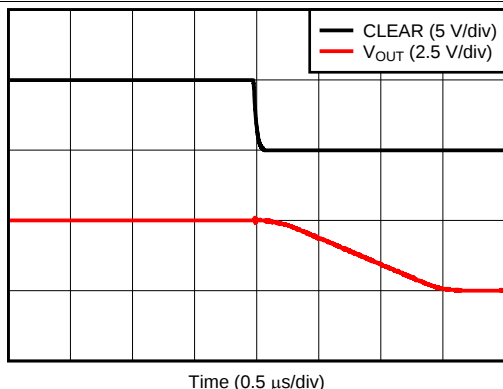
Gain = 1

D042

Figure 42. Power-On, Reset to Midscale

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.

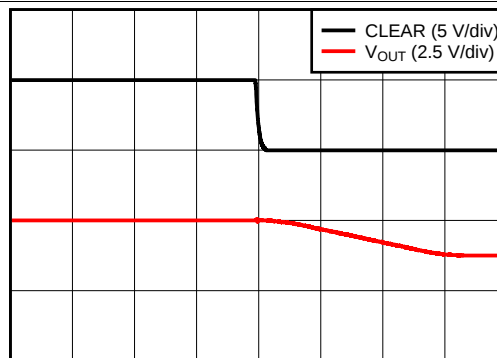


Time (0.5 $\mu\text{s}/\text{div}$)

D059

Gain = 1

Figure 43. DACx0508C, Clear to Zero Scale

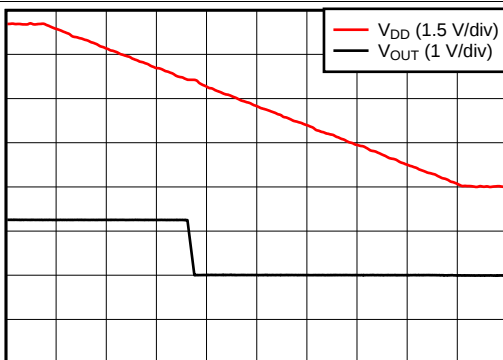


Time (0.5 $\mu\text{s}/\text{div}$)

D060

Gain = 1

Figure 44. DACx0508C, Clear to Midscale

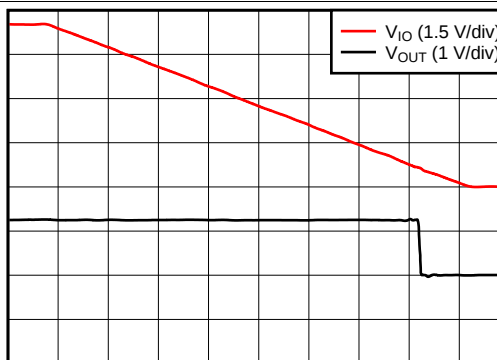


Time (600 $\mu\text{s}/\text{div}$)

D044

Gain = 1. DAC code at midscale

Figure 45. V_{DD} Power-Down

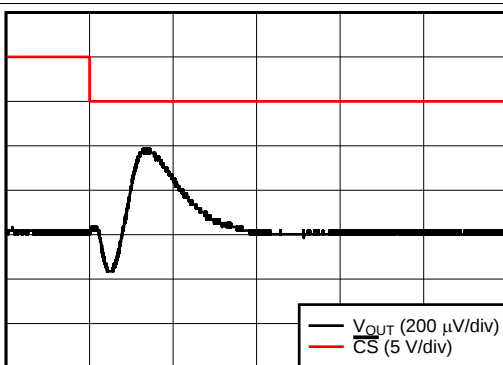


Time (600 $\mu\text{s}/\text{div}$)

D060

Gain = 1. DAC code at midscale

Figure 46. V_{IO} Power-Down

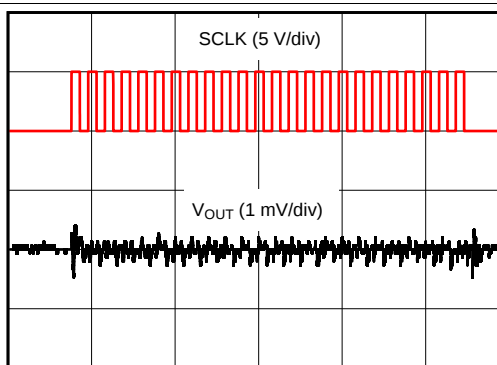


Time (2 $\mu\text{sec}/\text{div}$)

D045

Gain = 1. Measured DAC at midscale. All other DACs switch from code 32 to full scale

Figure 47. Channel to Channel Crosstalk



Time (5 $\mu\text{sec}/\text{div}$)

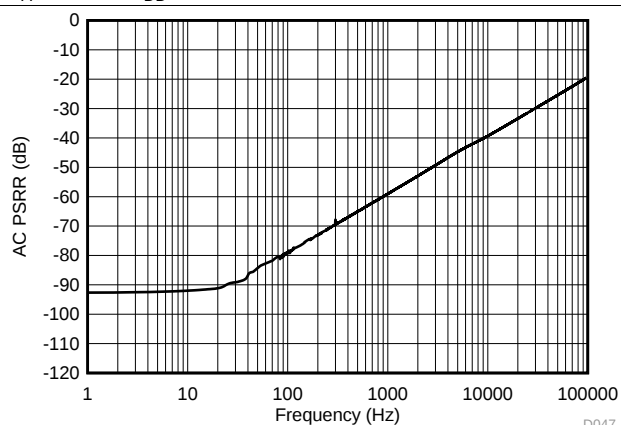
D046

Gain = 1. DAC code at midscale

Figure 48. Clock Feedthrough with SCLK = 1 MHz

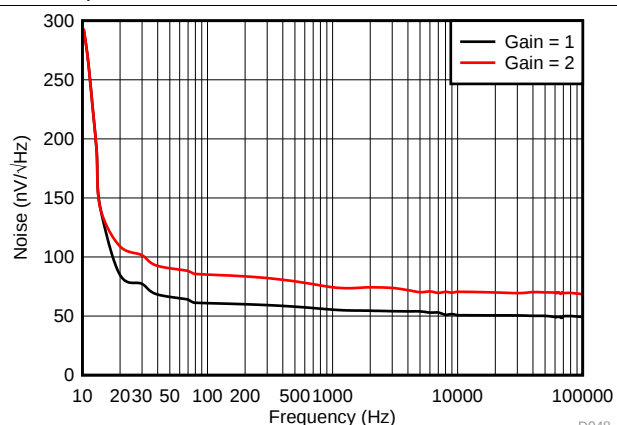
Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V , Gain = 2, DAC outputs unloaded, unless otherwise noted.



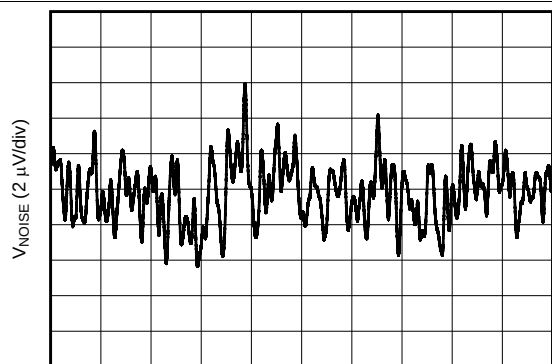
Gain = 1. $V_{DD} = 5\text{ V} + 200\text{ mV}_{PP}$ (Sinusoid). DAC code at fullscale

Figure 49. DAC Output AC PSRR vs Frequency



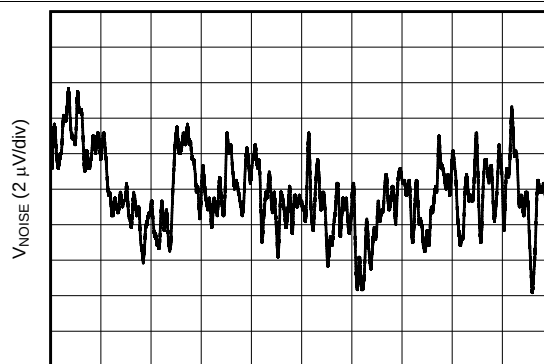
External Reference = 2.5 V . DAC code at midscale

Figure 50. DAC Output Noise Density vs Frequency



Gain = 1. External Reference = 2.5 V . DAC code at midscale

Figure 51. DAC Output Noise with External Reference
0.1 Hz to 10 Hz



Gain = 1. DAC code at midscale

Figure 52. DAC Output Noise with Internal Reference
0.1 Hz to 10 Hz

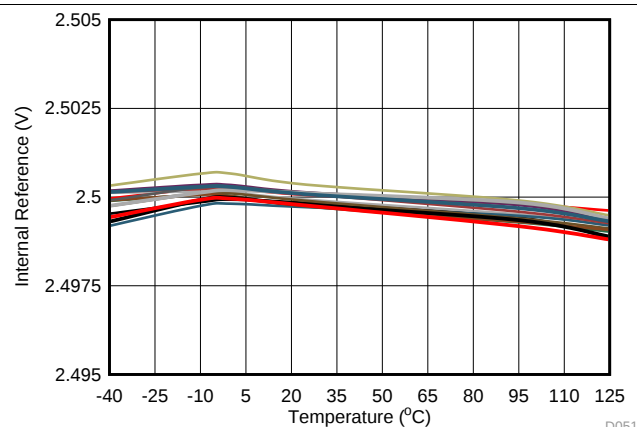


Figure 53. Internal Reference Voltage vs Temperature

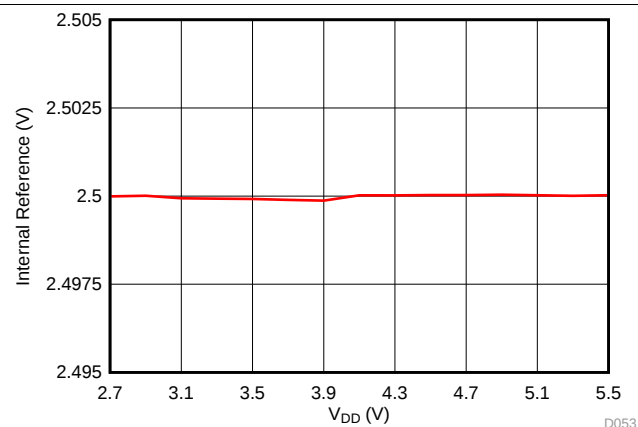
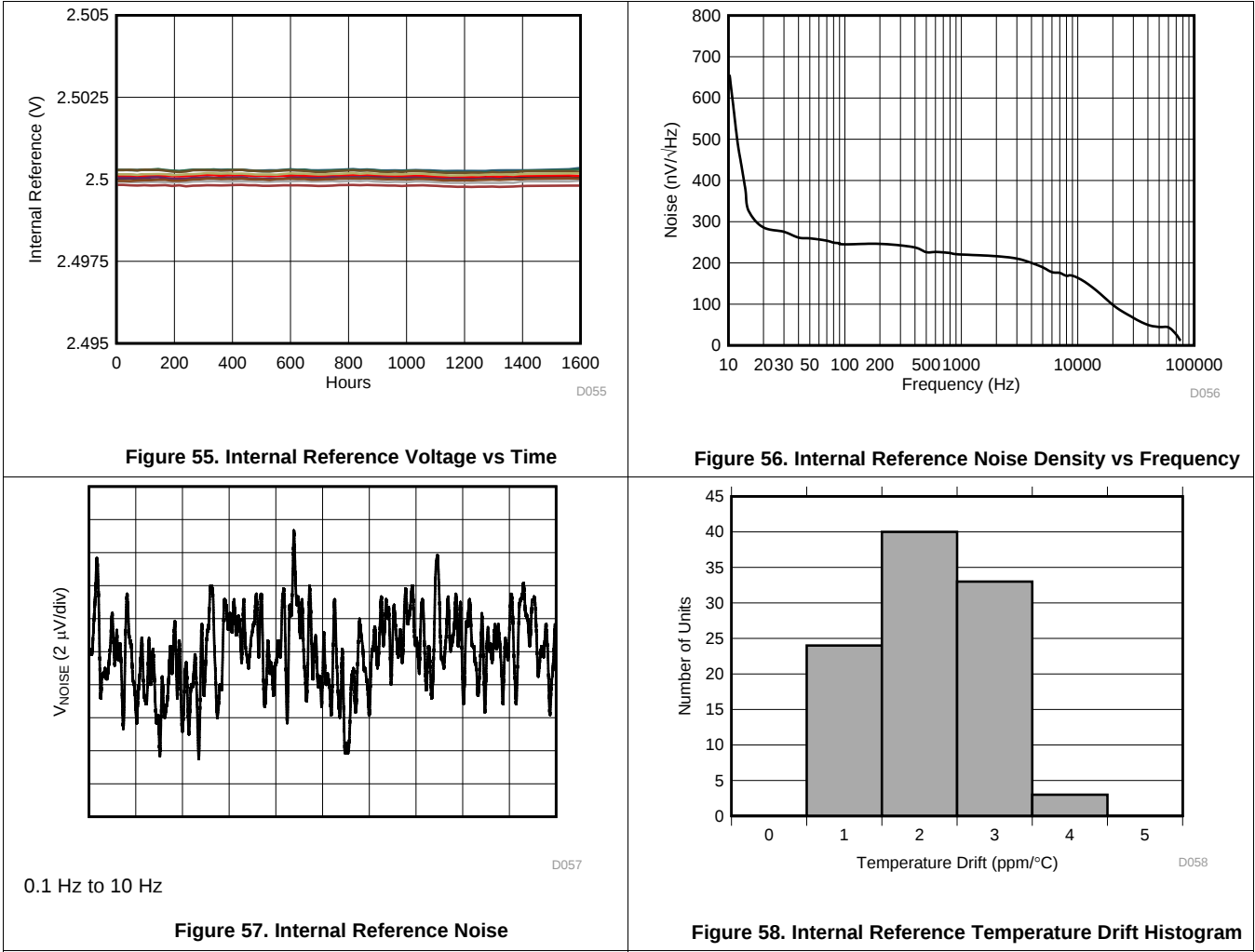


Figure 54. Internal Reference Voltage vs Supply Voltage

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, Internal Reference = 2.5 V, Gain = 2, DAC outputs unloaded, unless otherwise noted.



8 Detailed Description

8.1 Overview

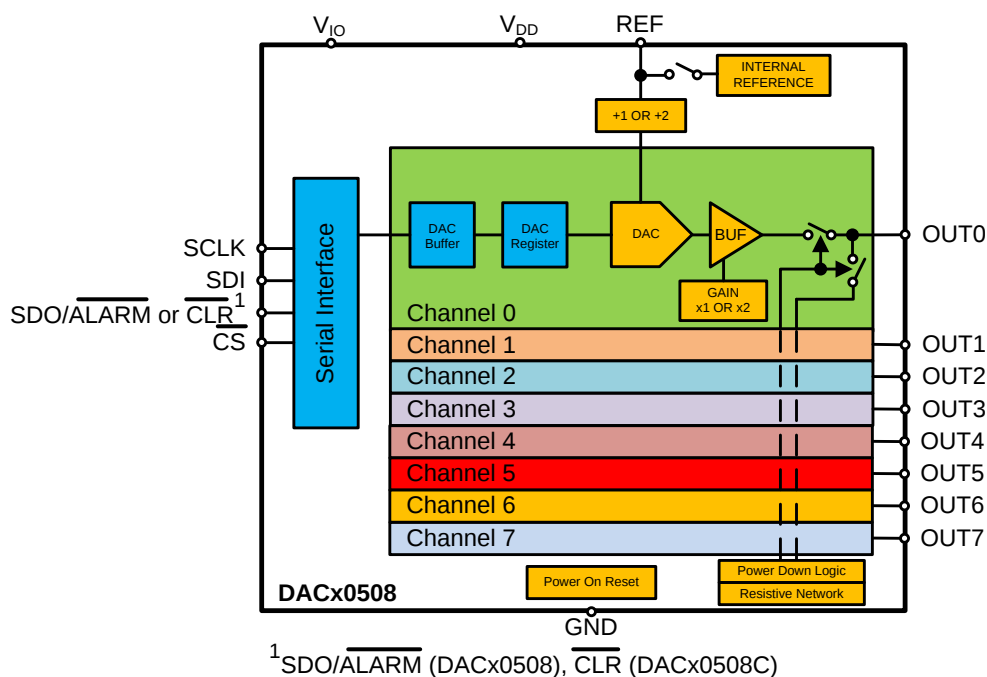
The DACx0508 is a pin-compatible family of low-power, eight-channel, buffered voltage-output digital-to-analog converters (DACs) with 16-, 14- and 12-bit resolution. The DACx0508 includes a 2.5 V internal reference and user selectable gain configuration providing full scale output voltages of 1.25 V (gain = $\frac{1}{2}$), 2.5 V (gain = 1) or 5 V (gain = 2). The device operates from a single 2.7 V to 5.5 V supply, is specified monotonic, and provides high linearity of ± 1 LSB INL.

Communication to the DACx0508 is performed through a serial interface that supports stand-alone and daisy-chain operation. The optional frame-error checking provides added robustness to the DACx0508 serial interface.

The DACx0508 incorporates a power-on-reset circuit that powers up and maintains the DAC outputs at either zero scale or midscale until a valid code is written to the device.

A dedicated clear pin (DACx0508C) enables a simultaneous update of multiple DAC channels to their power-on-reset value.

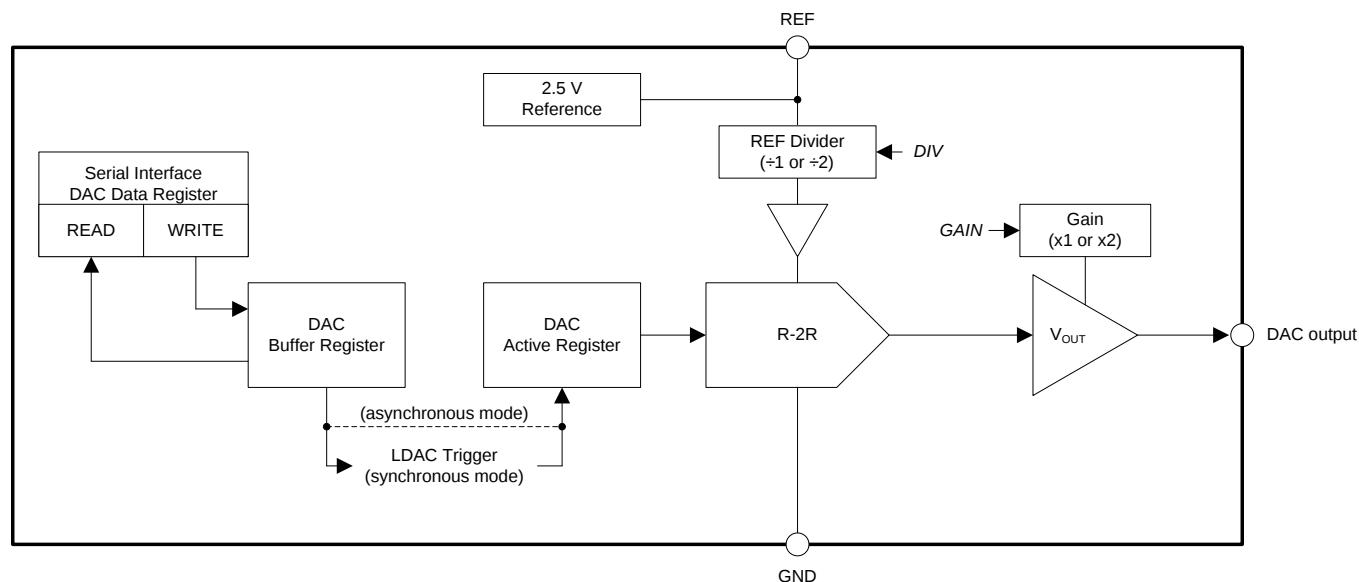
8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Digital-to-Analog Converter (DAC) Architecture

Each output channel in the DACx0508 consists of an R-2R ladder architecture followed by an output buffer amplifier. Figure 59 shows a block diagram of the DAC architecture.



Copyright © 2016, Texas Instruments Incorporated

Figure 59. DACx0508 DAC Block Diagram

8.3.1.1 DAC Transfer Function

The input data are written to the individual DAC Data registers in straight binary format. After a power-on or a reset event, all DAC registers are set to either zero code (DACx0508Z) or midscale code (DACx0508M). The DAC transfer function is given by Equation 1.

$$V_{OUT} = \frac{CODE}{2^n} \times \frac{V_{REF}}{DIV} \times GAIN \quad (1)$$

where:

CODE = decimal equivalent of the binary code that is loaded to the DAC register. CODE ranges from 0 to $2^n - 1$.

V_{REF} = DAC reference voltage. Either V_{REFOUT} from the internal 2.5 V reference or V_{REFIN} if using an external one.

n = resolution in bits. Either 12 (DAC60508), 14 (DAC70508) or 16 (DAC80508).

DIV = 1 or 2 as set by the REF-DIV bit in the GAIN register. Set to 1 by default.

GAIN = 1 or 2 as set by the BUFF-GAIN bit for that DAC channel in the GAIN register. Set to 1 by default in DACx0508Z and to 2 in DACx0508M.

Feature Description (continued)

8.3.1.2 Output Amplifiers

The DACx0508 output buffer amplifier is capable of generating rail-to-rail voltages on its output, giving a maximum output range of 0 V to V_{DD} . Each buffer amplifier is capable of driving a load of 2 k Ω in parallel with 10 nF to GND.

The full-scale output voltage for each channel is determined by the reference voltage (V_{REF}), the reference divider setting (DIV), and the output buffer gain for that channel (GAIN), as shown in Table 1. During normal operation the DIV and GAIN settings can be reconfigured through the REF-DIV and BUFF-GAIN bit (See Equation 1). The GAIN setting for each output channel can be individually configured thus enabling independent output voltage ranges for each DAC output.

Table 1. DAC Output Range Configuration

DIV Setting	GAIN Setting	DAC OUTPUT RANGE
$\div 2$	$\times 1$	0 V to $\frac{1}{2} \times V_{REF}$
$\div 1$	$\times 1$	Not recommended
$\div 2$	$\times 2$	0 V to V_{REF}
$\div 1$	$\times 2$	0 V to $2 \times V_{REF}$

8.3.1.3 DAC Register Structure

Data written to the DAC data registers is initially stored in the DAC buffer registers. Transfer of data from the DAC buffer registers to the active DAC registers can be configured to happen immediately (asynchronous mode) or initiated by an LDAC trigger (synchronous mode). Once the DAC active registers are updated, the DAC outputs change to their new values. When the host reads from a DAC Data register, the value held in the DAC buffer register is returned (not the value held in the DAC active register).

8.3.1.3.1 DAC Register Synchronous and Asynchronous Updates

The update mode for each DAC channel is determined by the status of its corresponding SYNC-EN bit. In asynchronous mode, a write to the DAC data register results in an immediate update of the DAC active register and DAC output on $\overline{CS}$ rising edge. In synchronous mode, writing to the DAC data register does not automatically update the DAC output. Instead the update occurs only after an LDAC trigger event. An LDAC trigger is generated through the LDAC bit in the TRIGGER register. The synchronous update mode enables simultaneous update of multiple DAC outputs. In both update modes a minimum wait time of 1 μ s is required between DAC output updates.

8.3.1.3.2 Broadcast DAC Register

The DAC broadcast register enables a simultaneous update of multiple DAC outputs with the same value with a single register write. Each DAC channel can be configured to update or remain unaffected by a broadcast command by setting the corresponding DAC-BROADCAST-EN bit in the SYNC register. A register write to the BROADCAST-DATA register forces those DAC channels that have been configured for broadcast operation to update their outputs. The DAC outputs update to the broadcast value on $\overline{CS}$ rising edge independently of their synchronous mode configuration.

8.3.1.3.3 CLEAR Operation (DACx0508C only)

The $\overline{CLR}$ pin enables a simultaneous update of multiple DAC channels to the clear value: zero code (DACx0508ZC) or midscale code (DACx0508MC). DAC channels 0 through 3 and channels 4 through 7 can be independently configured to update or remain unaffected by the $\overline{CLR}$ pin by setting the corresponding CLR-MSK bit. A $\overline{CLR}$ pin logic low forces those DAC channels that have been configured for clear operation to clear the contents of their buffer and active registers to the clear value and sets the analog outputs accordingly, regardless of their synchronization setting. Those channels not configured for clear operation retain their buffer and active register contents as well as the corresponding analog outputs even if a clear command is issued. While the $\overline{CLR}$ pin is kept low, register writes to the DAC data registers of those channels set for clear operation are ignored. A logic high on the $\overline{CLR}$ pin causes the device to exit clear mode.

8.3.2 Internal Reference

The DACx0508 includes a 2.5 V precision bandgap reference enabled by default. Operation from an external reference is supported by disabling the internal reference in the CONFIG register. The internal reference is externally available at the REF pin.

A minimum 150 nF capacitor is recommended between the reference output and GND for noise filtering.

8.3.2.1 Reference Divider

The reference voltage to the device, either from the internal reference or an external one can be divided by a factor of two by setting the REF-DIV bit in the GAIN register to 1 during normal operation. The reference voltage divider provides additional flexibility in setting the full-scale output voltage for each DAC output and must be configured so that there is sufficient headroom from V_{DD} to the DAC operating reference voltage (V_{REF}/DIV). See the [Recommended Operating Conditions](#) table for more information.

Improper configuration of the reference divider issues a reference alarm condition. In this case, the reference buffer is shut down, and all the DAC outputs go to 0 V. The DAC data registers are unaffected by the alarm condition thus enabling the DAC output to return to normal operation once the reference divider is configured correctly. The reference alarm status can be read from the REF-ALM bit in the STATUS register. Additionally by setting ALM-EN = 1 and ALM-SEL = 1 in the CONFIG register, the SDO/ALARM pin is configured as a reference alarm pin.

8.3.2.2 Solder Heat Reflow

A known behavior of IC reference voltage circuits is the shift induced by the soldering process. [Figure 60](#) and [Figure 61](#) show the effect of solder heat reflow for the DACx0508 internal reference.

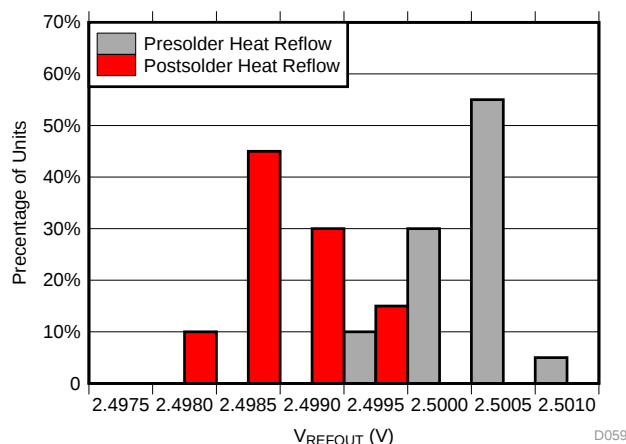


Figure 60. DAC70508 and DAC60508 Solder Heat Reflow Reference Voltage Shift

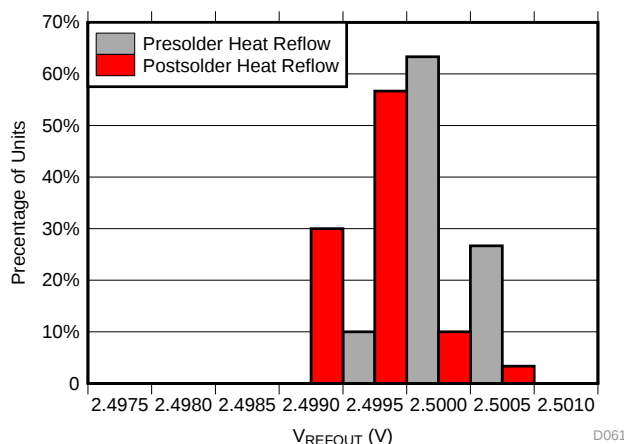


Figure 61. DAC80508 Solder Heat Reflow Reference Voltage Shift

8.3.3 Device Reset Options

8.3.3.1 Power-on-Reset (POR)

The DACx0508 includes a power-on reset function that controls the output voltage at power up. After the V_{DD} and V_{IO} supplies have been established a POR event is issued. The POR causes all registers to initialize to their default values and communication with the device is valid only after a 250 μ s power-on-reset delay. The default value for all DACs in the DACx0508Z devices is zero-code and midscale-code for the DACx0508M ones. Each DAC channel remains at the power-up voltage until a valid command is written to it.

The POR circuit requires specific supply levels to discharge the internal capacitors and to reset the device on power up, as indicated in Figure 62 and Figure 63. In order to ensure a POR event, V_{DD} or V_{IO} must be below their corresponding low thresholds for at least 100 μ s. If V_{DD} and V_{IO} remain above their specified high threshold a POR event will not occur. When the supplies drop below their high threshold but remain over the lower one (shown as the undefined region), the device may or may not reset under all specified temperature and power-supply conditions.

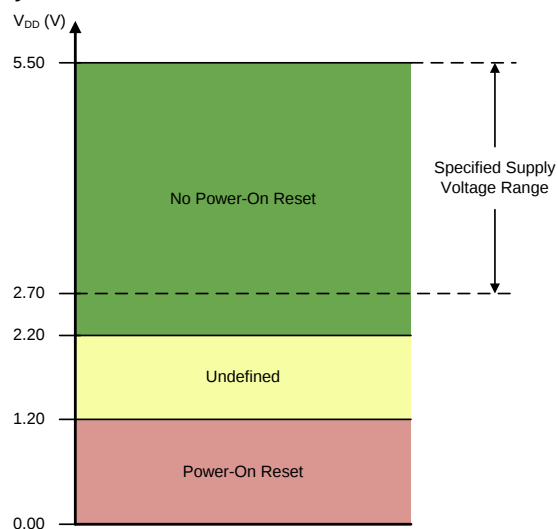


Figure 62. Threshold Levels for V_{DD} POR Circuit

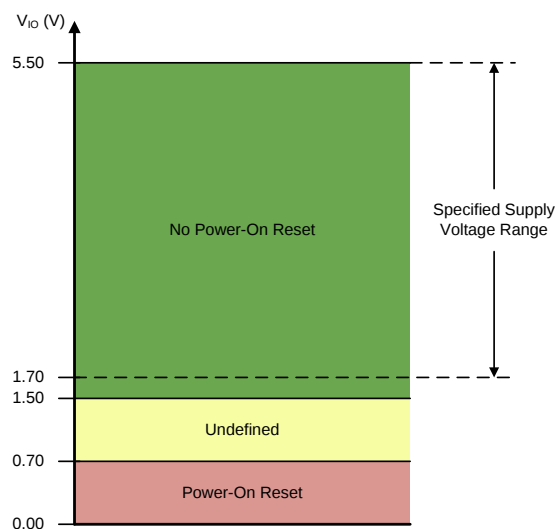


Figure 63. Threshold Levels for V_{IO} POR Circuit

8.3.3.2 Software Reset

A device software reset event is initiated by writing the reserved code 0x1010 to SOFT-RESET in the TRIGGER register. The software reset command is triggered on the $\overline{CS}$ rising edge of the instruction. A software reset initiates a POR event.

8.4 Device Functional Modes

8.4.1 Stand-Alone Operation

A serial interface access cycle is initiated by asserting the $\overline{\text{CS}}$ pin low. The serial clock SCLK can be a continuous or gated clock. SDI data are clocked on SCLK falling edges. A regular serial interface access cycle is 24 bits long with error checking disabled and 32 bits long with error checking enabled, thus the $\overline{\text{CS}}$ pin must stay low for at least 24 or 32 SCLK falling edges. The access cycle ends when the $\overline{\text{CS}}$ pin is de-asserted high. If the access cycle contains less than the minimum clock edges, the communication is ignored. If the access cycle contains more than the minimum clock edges, only the last 24 or 32 bits are used by the device. When $\overline{\text{CS}}$ is high, the SCLK and SDI signals are blocked and the SDO pin is in a Hi-Z state.

In an error checking disabled access cycle (24-bits long) the first byte input to SDI is the instruction cycle which identifies the request as a read or write command and the 4-bit address to be accessed. The following bits in the cycle form the data cycle, as shown in [Table 2](#).

Table 2. Serial Interface Access Cycle

BIT	FIELD	DESCRIPTION
23	RW	Identifies the communication as a read or write command to the addressed register. R/W = 0 sets a write operation. R/W = 1 sets a read operation.
22:20	Reserved	Reserved bits. Must be filled with zeros.
19:16	A[3:0]	Register address. Specifies the register to be accessed during the read or write operation.
15:0	DI[15:0]	Data cycle bits. If a write command, the data cycle bits are the values to be written to the register with address A[3:0]. If a read command, the data cycle bits are don't care values.

A read operation is initiated by issuing a read command access cycle. After the read command, a second access cycle must be issued to get the requested data, as shown in [Table 3](#). Data are clocked out on SDO pin either on the falling edge or rising edge of SCLK according to the FSDO bit in the CONFIG register.

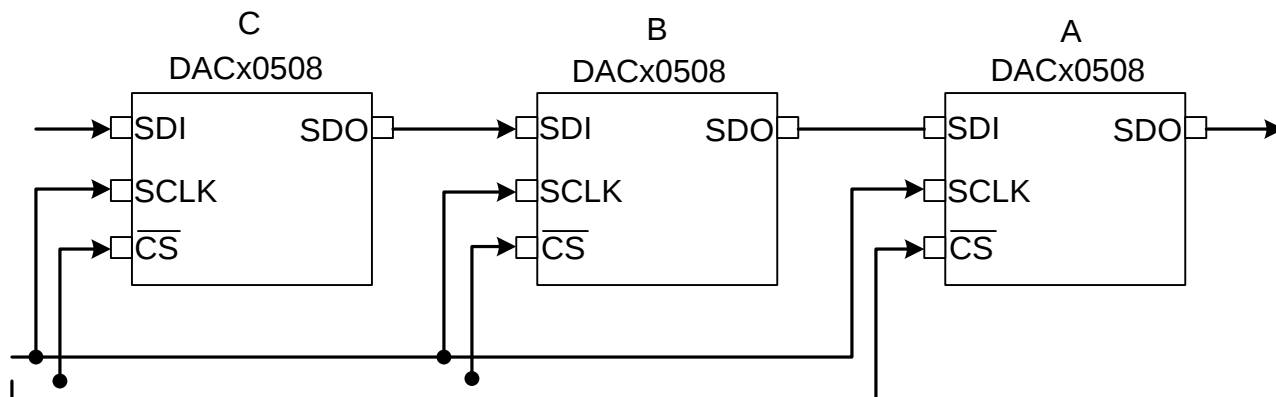
Table 3. SDO Output Access Cycle

BIT	FIELD	DESCRIPTION
23	RW	Echo RW from previous access cycle.
22:20	Reserved	Echo bits 22:20 from previous access cycle (all zeros).
19:16	A[3:0]	Echo address from previous access cycle.
15:0	DO[15:0]	Readback data requested on previous access cycle.

8.4.2 Daisy-Chain Operation

For systems that contain more than one DACx0508 devices, the SDO pin can be used to daisy-chain them together. Daisy-chain operation is useful in reducing the number of serial interface lines.

The first falling edge on the $\overline{\text{CS}}$ pin starts the operation cycle. If more than 24 SCLK pulses are applied while the $\overline{\text{CS}}$ pin is kept low, the data ripples out of the shift register and is clocked out on the SDO pin either on the falling edge or rising edge of SCLK according to the FSDO bit. By connecting the SDO output of the first device to the SDI input of the next device in the chain, a multiple-device interface is constructed. Each device in the system requires 24 clock pulses. As a result the total number of clock cycles must be equal to $24 \times N$, where N is the total number of DACx0508 devices in the daisy chain. When the serial transfer to all devices is complete the $\overline{\text{CS}}$ signal is taken high. This action transfers the data from the serial peripheral interface (SPI) shift registers to the internal registers of each device in the daisy chain and prevents any further data from being clocked into the input shift register.



Copyright © 2017, Texas Instruments Incorporated

Figure 64. Daisy-Chain Layout

8.4.3 Frame Error Checking

If the DACx0508 is used in a noisy environment, error checking can be used to check the integrity of SPI data communication between the device and the host processor. This feature can be enabled by setting the CRC-EN bit in the CONFIG register.

The error checking scheme is based on the CRC-8-ATM (HEC) polynomial $x^8 + x^2 + x + 1$ (that is, 100000111). When error checking is enabled, the serial interface access cycle width is 32 bits. The normal 24-bit SPI data is appended with an 8-bit CRC polynomial by the host processor before feeding it to the device, as shown in Table 4. In all serial interface readback operations the CRC polynomial is output on the SDO pin as part of the 32-bit cycle.

Table 4. Error Checking Serial Interface Access Cycle

BIT	FIELD	DESCRIPTION
31	RW	Identifies the communication as a read or write command to the addressed register. R/W = 0 sets a write operation. R/W = 1 sets a read operation.
30	CRC-ERROR	Reserved bit. Set to zero.
29:28	Reserved	Reserved bits. Must be filled with zeros.
27:24	A[3:0]	Register address. Specifies the register to be accessed during the read or write operation.
23:8	DI[15:0]	Data cycle bits. If a write command, the data cycle bits are the values to be written to the register with address A[3:0]. If a read command, the data cycle bits are don't care values.
7:0	CRC	8-bit CRC polynomial.

The DACx0508 decodes the 32-bit access cycle to compute the CRC remainder on $\overline{CS}$ rising edges. If no error exists, the CRC remainder is zero and data are accepted by the device.

A write operation failing the CRC check causes the data to be ignored by the device. After the write command, a second access cycle can be issued to determine the error checking result (CRC-ERROR bit) on the SDO pin, as shown in Table 5. Additionally, by setting ALM-EN = 1 and ALM-SEL = 0 in the CONFIG register, the SDO/ALARM pin is configured as a CRC alarm pin.

Table 5. Write Operation Error Checking Cycle

BIT	FIELD	DESCRIPTION
31	RW	Echo RW from previous access cycle (RW = 0).
30	CRC-ERROR	Returns a 1 when a CRC error is detected, 0 otherwise.
29:28	Reserved	Echo bits 29:28 from previous access cycle (all zeros).
27:24	A[3:0]	Echo address from previous access cycle.
23:8	DO[15:0]	Echo data from previous access cycle.
7:0	CRC	Calculated CRC value of bits 31:8.

A read operation must be followed by a second access cycle to get the requested data on the SDO pin. The error check result (CRC-ERROR bit) from the read command is output on the SDO pin, as shown in Table 6. As in the case of a write operation failing the CRC check, the SDO/ALARM pin if configured as a CRC alarm pin can be used to indicate a read command CRC failure.

Table 6. Read Operation Error Checking Cycle

BIT	FIELD	DESCRIPTION
31	RW	Echo RW from previous access cycle (RW = 1).
30	CRC-ERROR	Returns a 1 when a CRC error is detected, 0 otherwise.
29:28	Reserved	Echo bits 29:28 from previous access cycle (all zeros).
27:24	A[3:0]	Echo address from previous access cycle.
23:8	DO[15:0]	Readback data requested on previous access cycle.
7:0	CRC	Calculated CRC value of bits 31:8.

8.4.4 Power-Down Mode

The DACx0508 DAC output amplifiers and internal reference can be independently powered down through the CONFIG register. At power-up all output channels and the device internal reference are active by default. A DAC output channel in power-down mode is connected internally to GND through a 1 k Ω resistor.

8.5 Programming

The DACx0508 is controlled through a flexible serial interface that is compatible with SPI type interfaces used on many microcontrollers and DSP controllers. [Table 7](#) shows the SPI timing requirements. [Figure 65](#) and [Figure 66](#) show the SPI write and read timing diagrams, respectively.

Table 7. Programming Timing Requirements⁽¹⁾

		V _{IO} = 1.7 V to 2.7 V			V _{IO} = 2.7 V to 5.5 V			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
SERIAL INTERFACE – WRITE OPERATION								
f _{SCLK}	SCLK frequency	50			50			MHz
t _{SCLKHIGH}	SCLK high time	9			9			ns
t _{SCLKLOW}	SCLK low time	9			9			ns
t _{SDIS}	SDI setup	5			5			ns
t _{SDIH}	SDI hold	10			10			ns
t _{CSS}	$\overline{\text{CS}}$ to SCLK falling edge setup	13			13			ns
t _{CSH}	SCLK falling edge to $\overline{\text{CS}}$ rising edge	10			10			ns
t _{CSHIGH}	$\overline{\text{CS}}$ high time	15			15			ns
t _{CSIGNORE}	SCLK falling edge to $\overline{\text{CS}}$ ignore	7			7			ns
SERIAL INTERFACE – READ AND DAISY CHAIN OPERATION, FSDO = 0								
f _{SCLK}	SCLK frequency	12			18			MHz
t _{SCLKHIGH}	SCLK high time	35			25			ns
t _{SCLKLOW}	SCLK low time	35			25			ns
t _{SDIS}	SDI setup	5			5			ns
t _{SDIH}	SDI hold	10			10			ns
t _{CSS}	$\overline{\text{CS}}$ to SCLK falling edge setup	32			20			ns
t _{CSH}	SCLK falling edge to $\overline{\text{CS}}$ rising edge	10			10			ns
t _{CSHIGH}	$\overline{\text{CS}}$ high time	15			15			ns
t _{SDODLY}	SDO output delay from SCLK rising edge	3.5 33.5			3.5 23			ns
t _{SDODZ}	SDO driven to tri-state	0 30			0 25			ns
t _{CSIGNORE}	SCLK falling edge to $\overline{\text{CS}}$ ignore	7			7			ns
SERIAL INTERFACE – READ AND DAISY CHAIN OPERATION, FSDO = 1								
f _{SCLK}	SCLK frequency	20			25			MHz
t _{SCLKHIGH}	SCLK high time	22			18			ns
t _{SCLKLOW}	SCLK low time	22			18			ns
t _{SDIS}	SDI setup	5			5			ns
t _{SDIH}	SDI hold	10			10			ns
t _{CSS}	$\overline{\text{CS}}$ to SCLK falling edge setup	32			20			ns
t _{CSH}	SCLK falling edge to $\overline{\text{CS}}$ rising edge	10			10			ns
t _{CSHIGH}	$\overline{\text{CS}}$ high time	15			15			ns
t _{SDODLY}	SDO output delay from SCLK falling edge	3.5 45			3.5 32			ns
t _{SDODZ}	SDO driven to tri-state	0 30			0 25			ns
t _{CSIGNORE}	SCLK falling edge to $\overline{\text{CS}}$ ignore	7			7			ns
DIGITAL LOGIC								
t _{RSTDLYPOR}	POR reset delay	170 250			170 250			μs
t _{DACWAIT}	Sequential DAC output updates	1			1			μs
t _{CLR}	$\overline{\text{CLR}}$ pulse	20			20			ns
t _{CLRD}	$\overline{\text{CLR}}$ delay ⁽²⁾	100			100			ns

(1) All input signals are specified with $t_R = t_F = 1 \text{ ns/V}$ (10% to 90% of V_{IO}), timed from a voltage level of $(V_{IL} + V_{IH})/2$, $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$, $V_{IO} = 1.7 \text{ V to } 5.5 \text{ V}$, $V_{REFIN} = 1.25 \text{ V to } 5.5 \text{ V}$, SDO loaded with 20 pF, $T_A = -40^\circ\text{C to } +125^\circ\text{C}$

(2) Specified from a logic-low on $\overline{CLR}$ pin to when the DAC output starts to change. In the special case when the DAC output is at GND or V_{DD} , the $\overline{CLR}$ delay may be as long as 1 μs

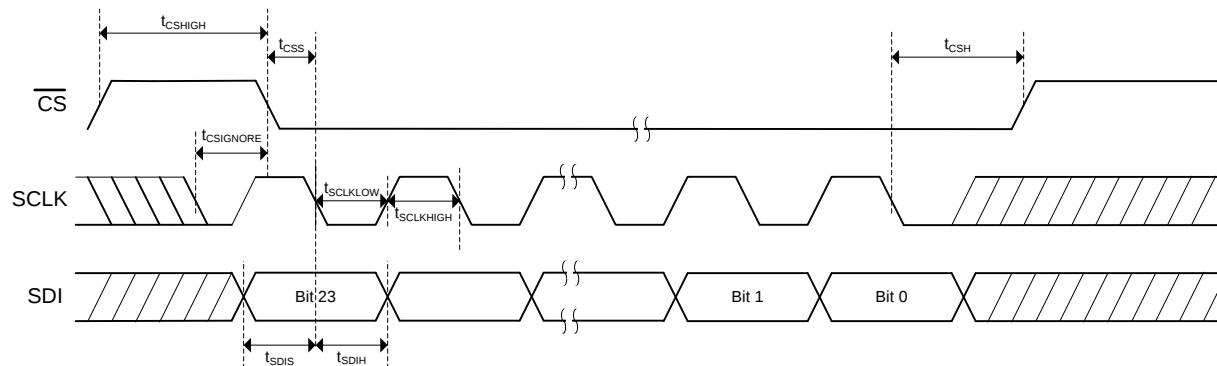


Figure 65. Serial Interface Write Timing Diagram

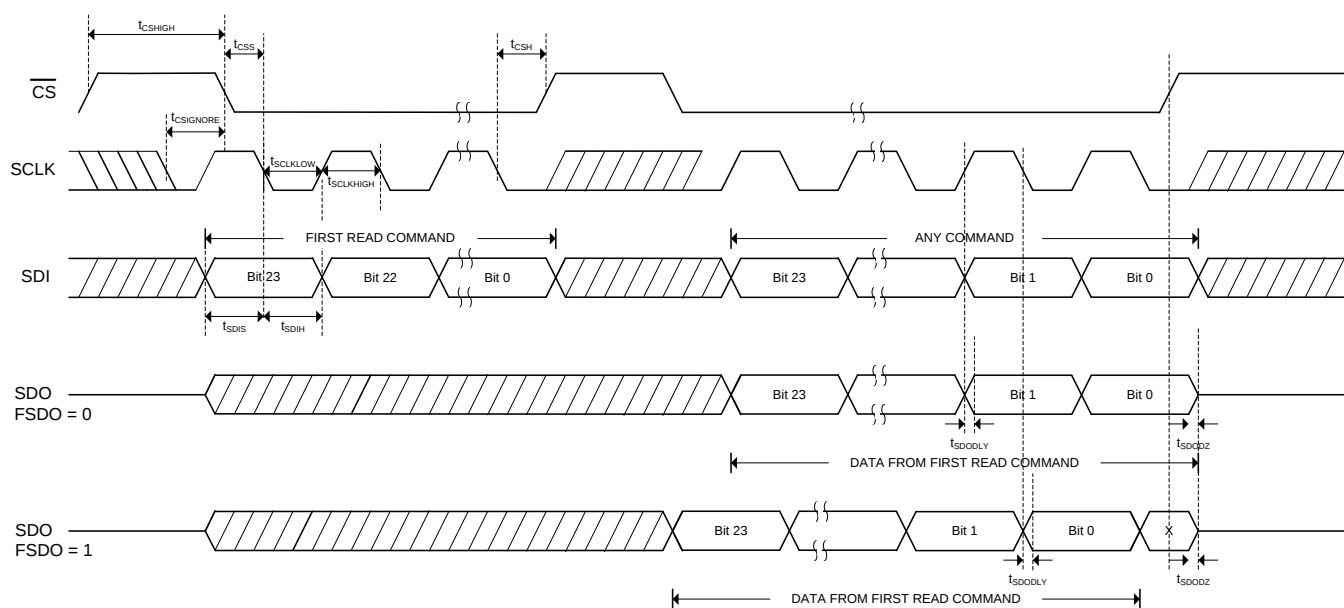


Figure 66. Serial Interface Read Timing Diagram

8.6 Register Map

Table 8. Register Map

REGISTER	TYPE	RESET	ADDRESS BITS				DATA BITS															
			A3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
NOP	W	0000	0	0	0	0	NOP															
DEVICE ID	R	—	0	0	0	1	DEVICEID															VERSIONID
SYNC	R/W	FF00	0	0	1	0	DACx-BROADCAST-EN						DACx-SYNC-EN									
CONFIG	R/W	0000	0	0	1	1	RESERVED	ALM SEL	ALM EN	CRC EN	F SDO	D SDO	REF PW DWN	DACx-PWDWN								
GAIN	R/W	0000	0	1	0	0	RESERVED				CLR-4TO 7 -MSK ⁽¹⁾	CLR-0TO 3 -MSK ⁽¹⁾	REF DIV-EN	BUFFx-GAIN								
TRIGGER	W	0000	0	1	0	1	RESERVED											L DAC	SOFT-RESET[3:0]			
BRDCAST	R/W	0000	0	1	1	0	BRDCAST-DATA[15:0]															
STATUS	R/W	0000	0	1	1	1	RESERVED															REF ALM
DAC0	R/W	0000	1	0	0	0	DAC0-DATA[15:0]															
DAC1	R/W	0000	1	0	0	1	DAC1-DATA[15:0]															
DAC2	R/W	0000	1	0	1	0	DAC2-DATA[15:0]															
DAC3	R/W	0000	1	0	1	1	DAC3-DATA[15:0]															
DAC4	R/W	0000	1	1	0	0	DAC4-DATA[15:0]															
DAC5	R/W	0000	1	1	0	1	DAC5-DATA[15:0]															
DAC6	R/W	0000	1	1	1	0	DAC6-DATA[15:0]															
DAC7	R/W	0000	1	1	1	1	DAC7-DATA[15:0]															
All Others	—	—	—	—	—	—	RESERVED															

(1) DACx0508C only. Reserved bits in DACx0508.

8.6.1 NOP Register (address = 0x00) [reset = 0x0000]**Figure 67. NOP Register**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
NOP															
W															

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 9. NOP Register Field Descriptions

Bit	Field	Type	Reset	Description
15:0	NOP	W	0x0000	No operation. Write 0000h for proper no-operation command

8.6.2 DEVICE ID Register (address = 0x01) [reset = 0x---]**Figure 68. DEVICE ID Register**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
DEVICEID														VERSIONID	
R														R	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 10. DEVICE ID Field Descriptions

Bit	Field	Type	Reset	Description
15:2	DEVICEID	R	----	Device ID: D15 Reserved - 0 D14:12 Resolution - 000 (16-bit); 001 (14-bit); 010 (12-bit) D11:8 Channels - 1000 (8 channels) D7 Reset - 0 (DACx0508Z: reset to zero); 1 (DACx0508M: reset-to-midscale) D6:2 Reserved - 00101
1:0	VERSIONID	R	10	Version ID. Subject to change

8.6.3 SYNC Register (address = 0x2) [reset = 0xFF00]**Figure 69. SYNC Register**

15	14	13	12	11	10	9	8
DAC7-BROADCAST-EN	DAC6-BROADCAST-EN	DAC5-BROADCAST-EN	DAC4-BROADCAST-EN	DAC3-BROADCAST-EN	DAC2-BROADCAST-EN	DAC1-BROADCAST-EN	DAC0-BROADCAST-EN
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
7	6	5	4	3	2	1	0
DAC7-SYNC-EN	DAC6-SYNC-EN	DAC5-SYNC-EN	DAC4-SYNC-EN	DAC3-SYNC-EN	DAC2-SYNC-EN	DAC1-SYNC-EN	DAC0-SYNC-EN
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 11. SYNC Register Field Descriptions

Bit	Field	Type	Reset	Description
15	DAC7-BROADCAST-EN	R/W	1	When set to 1 the corresponding DAC is set to update its output after a serial interface write to the BROADCAST register. When cleared to 0 the corresponding DAC output remains unaffected after a serial interface write to the BROADCAST register.
14	DAC6-BROADCAST-EN	R/W	1	
13	DAC5-BROADCAST-EN	R/W	1	
12	DAC4-BROADCAST-EN	R/W	1	
11	DAC3-BROADCAST-EN	R/W	1	
10	DAC2-BROADCAST-EN	R/W	1	
9	DAC1-BROADCAST-EN	R/W	1	
8	DAC0-BROADCAST-EN	R/W	1	
7	DAC7-SYNC-EN	R/W	0	When set to 1 the corresponding DAC output is set to update in response to an LDAC trigger (synchronous mode). When cleared to 0 the corresponding DAC output is set to update immediately on a CS rising edge (asynchronous mode).
6	DAC6-SYNC-EN	R/W	0	
5	DAC5-SYNC-EN	R/W	0	
4	DAC4-SYNC-EN	R/W	0	
3	DAC3-SYNC-EN	R/W	0	
2	DAC2-SYNC-EN	R/W	0	
1	DAC1-SYNC-EN	R/W	0	
0	DAC0-SYNC-EN	R/W	0	

8.6.4 CONFIG Register (address = 0x3) [reset = 0x0000]

Figure 70. CONFIG Register

15	14	13	12	11	10	9	8
Reserved		ALM-SEL	ALM-EN	CRC-EN	FSDO	DSDO	REF-PWDWN
—		R/W	R/W	R/W	R/W	R/W	R/W
7	6	5	4	3	2	1	0
DAC7-PWDWN	DAC6-PWDWN	DAC5-PWDWN	DAC4-PWDWN	DAC3-PWDWN	DAC2-PWDWN	DAC1-PWDWN	DAC0-PWDWN
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 12. CONFIG Register Field Descriptions

Bit	Field	Type	Reset	Description
15:14	Reserved	—	00	Reserved for factory use
13	ALM-SEL	R/W	0	ALARM select. 0: $\overline{\text{ALARM}}$ pin is CRC-ERROR 1: $\overline{\text{ALARM}}$ pin is REF-ALARM
12	ALM-EN	R/W	0	Configure SDO/ $\overline{\text{ALARM}}$ pin. When 1: SDO/ $\overline{\text{ALARM}}$ pin is an active-low, open-drain, alarm pin. An external 10 k Ω pullup resistor to V_{IO} is required. FSDO and DSDO bits are ignored. When 0: SDO/ $\overline{\text{ALARM}}$ pin is a serial interface, push-pull, SDO pin
11	CRC-EN	R/W	0	CRC enable bit. Set to 1 to enable CRC. Set to 0 to disable
10	FSDO	R/W	0	Fast SDO bit (half-cycle speedup). When 0, SDO updates on an SCLK rising edge. When 1, SDO updates a half-cycle earlier, during an SCLK falling edge.
9	DSDO	R/W	0	Disable SDO bit. When 1, SDO is always tri-stated. When 0, SDO is driven while $\overline{\text{CS}}$ is low, and tri-stated while $\overline{\text{CS}}$ is high
8	REF-PWDWN	R/W	0	When set to 1 disables the device internal reference
7	DAC7-PWDWN	R/W	0	When set to 1 the corresponding DAC is set in power-down mode and its output is connected to GND through a 1 k Ω internal resistor.
6	DAC6-PWDWN	R/W	0	
5	DAC5-PWDWN	R/W	0	
4	DAC4-PWDWN	R/W	0	
3	DAC3-PWDWN	R/W	0	
2	DAC2-PWDWN	R/W	0	
1	DAC1-PWDWN	R/W	0	
0	DAC0-PWDWN	R/W	0	

8.6.5 GAIN Register (address = 0x04) [reset = 0x---]**Figure 71. GAIN Register**

15	14	13	12	11	10	9	8
Reserved					Reserved/ CLR-4TO7- MSK ⁽¹⁾	Reserved/ CLR-0TO3- MSK ⁽¹⁾	REFDIV-EN
—					R/W	R/W	R/W
7	6	5	4	3	2	1	0
BUFF7-GAIN	BUFF6-GAIN	BUFF5-GAIN	BUFF4-GAIN	BUFF3-GAIN	BUFF2-GAIN	BUFF1-GAIN	BUFF0-GAIN
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

(1) DACx0508C only. Reserved bits in DACx0508.

Table 13. GAIN Register Field Descriptions

Bit	Field	Type	Reset	Description
15:11	Reserved	—	0	Reserved for factory use.
10	Reserved / CLR-4TO7-MSK	R/W	0	DACx0508. Reserved for factory use.
9	Reserved / CLR-0TO3-MSK	R/W	0	DACx0508C. When cleared to 0 the corresponding DAC group is set to clear in response to a logic-low value on the CLR pin. When set to 1 the corresponding DAC group remains unaffected by the CLR pin.
8	REFDIV-EN	R/W	0/1	When set to 1 the reference voltage is internally divided by a factor of 2. When cleared to 0 the reference voltage is unaffected.
7	BUFF7-GAIN	R/W	0/1	When set to 1 the buffer amplifier for corresponding DAC has a gain of 2. Default value for the DACx0508M devices. When cleared to 0 the buffer amplifier for corresponding DAC has a gain of 1. Default value for the DACx0508Z devices.
6	BUFF6-GAIN	R/W	0/1	
5	BUFF5-GAIN	R/W	0/1	
4	BUFF4-GAIN	R/W	0/1	
3	BUFF3-GAIN	R/W	0/1	
2	BUFF2-GAIN	R/W	0/1	
1	BUFF1-GAIN	R/W	0/1	
0	BUFF0-GAIN	R/W	0/1	

8.6.6 TRIGGER Register (address = 0x05) [reset = 0x0000]**Figure 72. TRIGGER Register**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved											LDAC	SOFT-RESET[3:0]			
—											W	W			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 14. TRIGGER Register Field Descriptions

Bit	Field	Type	Reset	Description
15:5	Reserved	—	0	Reserved for factory use.
4	LDAC	W	0	Set this bit to 1 to synchronously load those DACs that have been set in synchronous mode in the SYNC register.
3:0	SOFT-RESET[3:0]	W	0x0	When set to the reserved code 1010 resets the device to its default state.

8.6.7 BRDCAST Register (address = 0x6) [reset = 0x0000]**Figure 73. BRDCAST Register**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
BRDCAST-DATA[15:0]															
R/W															

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 15. BRDCAST Register Field Descriptions

Bit	Field	Type	Reset	Description
15:0	BRDCAST-DATA[15:0]	R/W	0x0000	Writing to the BRDCAST register forces those DAC channels that have been set to broadcast in the SYNC register to update their active data register with the BRDCAST-DATA value. Data are MSB aligned in straight binary format and follows the format below: DAC80508: { DATA[15:0] } DAC70508: { DATA[13:0], x, x } DAC60508: { DATA[11:0], x, x, x, x } x – Don't care bits

8.6.8 STATUS Register (address = 0x7) [reset = 0x0000]**Figure 74. STATUS Register**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Reserved														REF-ALM	
—														R/W	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 16. STATUS Register Field Descriptions

Bit	Field	Type	Reset	Description
15:1	Reserved	—	0	Reserved for factory use.
0	REF-ALM	R	0	Reference alarm bit. Reads 1 when the difference between V_{REF}/DIV and V_{DD} is below the required minimum analog threshold. Reads 0 otherwise.

8.6.9 DACx Register (address = 0x8 to 0xF) [reset = 0x0000 or 0x8000]**Figure 75. DACx Register**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
DACx-DATA[15:0]															
R/W															

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 17. DACx Register Field Descriptions

Bit	Field	Type	Reset	Description
15:0	DACx-DATA[15:0]	R/W	0x0000 or 0x8000	Stores the 16-, 14- or 12-bit data to be loaded to DACx in MSB aligned straight binary format. The default value is zero-code for the DACx0508Z devices and midscale-code for the DACx0508M ones. Data follows the format below: DAC80508: { DATA[15:0] } DAC70508: { DATA[13:0], x, x } DAC60508: { DATA[11:0], x, x, x, x } x – Don't care bits

9 Application and Implementation

NOTE

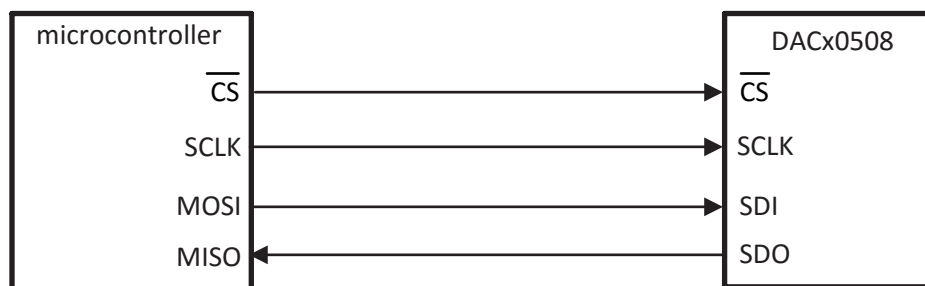
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The high linearity, small package size and wide temperature range make the DACx0508 suitable in applications such as optical networking, wireless infrastructure, industrial automation and data acquisition systems. The device incorporates a 2.5 V internal reference with an internal reference divider circuit that enables full-scale DAC output voltages of 1.25 V, 2.5 V, or 5 V.

9.1.1 Interfacing to Microcontroller

Figure 76 displays a typical serial interface that may be observed when connecting the DACx0508 SPI serial interface to a (master) microcontroller type platform. The setup for the interface is as follows: The microcontroller output SPI CLK drives the SCLK pin of the DACx0508, while the DACx0508 SDI pin is driven by the MOSI pin of the microcontroller. The $\overline{\text{CS}}$ pin of the DACx0508 can be asserted from a general program input/output pin of the microcontroller. When data are to be transmitted to the DACx0508, the $\overline{\text{CS}}$ pin is taken low. The data from the microcontroller is then transmitted to the DACx0508, totaling 24 bits latched into the DACx0508 device through the falling edge of SCLK. $\overline{\text{CS}}$ is then brought high after the completed write. The DACx0508 requires data with the MSB as the first bit received.



Copyright © 2017, Texas Instruments Incorporated

Figure 76. Typical Serial Interface

Application Information (continued)

9.1.2 Programmable Current Source Circuit

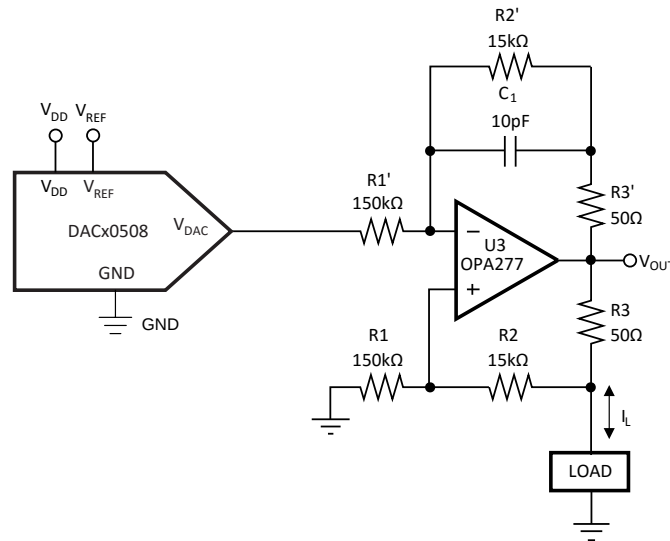
The DACx0508 can be integrated into the circuit in [Figure 77](#) to implement an improved Howland current pump for precise voltage to current conversions. Bidirectional current flow and high voltage compliance are two features of the circuit. With a matched resistor network, the load current of the circuit is shown by [Equation 2](#).

$$I_L = \frac{(R2 + R3) / R1}{R3} \times V_{REF} \times \frac{CODE}{2^n} \quad (2)$$

The value of R3 in [Equation 2](#) can be reduced to increase the output current drive of U3. U3 can drive ± 20 mV in both directions with voltage compliance limited up to 15 V by the U3 voltage supply. Elimination of the circuit compensation capacitor C1 in the circuit is not suggested as a result of the change in the output impedance Z_O , according to [Equation 3](#).

$$Z_O = \frac{(R1')(R3)(R1 + R2)}{R1(R2' + R3') - R1'(R2 + R3)} \quad (3)$$

As shown in [Equation 3](#), with matched resistors, Z_O is infinite and the circuit is optimum for use as a current source. However, if unmatched resistors are used, Z_O is positive or negative with negative output impedance being a potential cause of oscillation. Therefore, by incorporating C1 into the circuit, possible oscillation problems are eliminated. The value of C1 can be determined for critical applications; for most applications, however, a value of several pF is suggested.

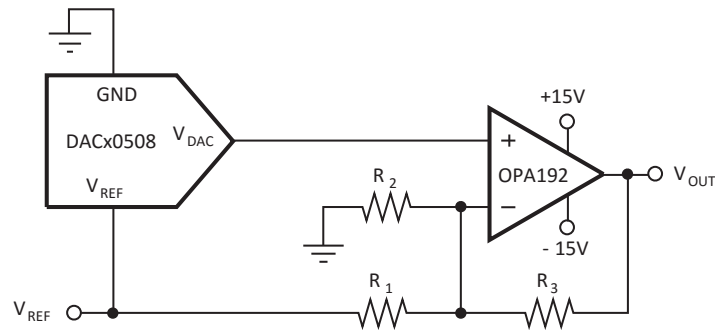


Copyright © 2017, Texas Instruments Incorporated

Figure 77. Programmable Bidirectional Current Source Circuit

9.2 Typical Application

The DACx0508 is designed for single-supply operation; however, a bipolar output is also possible using the circuit shown in [Figure 78](#).



NOTE: Some pins omitted for clarity.

Copyright © 2017, Texas Instruments Incorporated

Figure 78. Bipolar Operation Using the DACx0508

9.2.1 Design Requirements

The circuit shown in [Figure 78](#) gives a bipolar output voltage at V_{OUT} . When $GAIN = 1$, V_{OUT} can be calculated using [Equation 4](#):

$$V_{OUT}(\text{CODE}) = \left[\left(V_{REF} \times \frac{\text{CODE}}{2^n} \right) \left(1 + \frac{R_3}{R_2} + \frac{R_3}{R_1} \right) - \left(V_{REF} \times \frac{R_3}{R_1} \right) \right] \quad (4)$$

Where:

- $V_{OUT}(\text{CODE})$ = output voltage versus code
- $\text{CODE} = 0$ to $2^n - 1$. This is the digital code loaded to the DAC
- V_{REF} = reference voltage applied to the DACx0508
- n = resolution in bits. Either 12 (DAC60508), 14 (DAC70508) or 16 (DAC80508)

Table 18. Design Parameters

PARAMETER	VALUE
V_{OUT}	± 10 V
V_{REF}	2.5 V
n	12

9.2.2 Detailed Design Procedure

The bipolar output span can be calculated through [Equation 4](#) by defining a few parameters, the first being the value for the reference voltage. Once a reference voltage is chosen, the gain resistors can be set accordingly by determining the desired V_{OUT} at code 0 and code 2^n . For a V_{REF} of 2.5 V and a desired output voltage range of ± 10 V the calculation is as follows.

CODE = 0:

$$V_{OUT}(0) - \left(V_{REF} \times \frac{R_3}{R_1} \right) = - \left(2.5V \times \frac{R_3}{R_1} \right) \quad (5)$$

Setting the equation to minimum output span, $V_{OUT}(0) = -10$ V, will reduce the equation to: $R_3/R_1 = 4$:

CODE = 4096:

Setting the equation to maximum output scan, $V_{OUT}(4096) = 10$ V, and $R_3/R_1 = 4$ will reduce the equation to: $R_3/R_2 = 3$

It is important to note that the maximum code of a 12-bit DAC is 4095; code 4096 was used to simplify the equation above. For practical use, the true output span will encompass a range of -10 V to $(10\text{ V} - 1\text{ LSB})$, which in this case is -10 V to 9.995 V .

9.2.3 Application Curve

The $\pm 10\text{ V}$ output span with a reference voltage of 2.5 V can be achieved by using values of $30\text{ k}\Omega$, $10\text{ k}\Omega$, and $7.5\text{ k}\Omega$ for R_3 , R_2 , and R_1 respectively. A curve to illustrate this output span is shown in [Figure 79](#). Note: 1% tolerance resistors were used in evaluating bipolar operation.

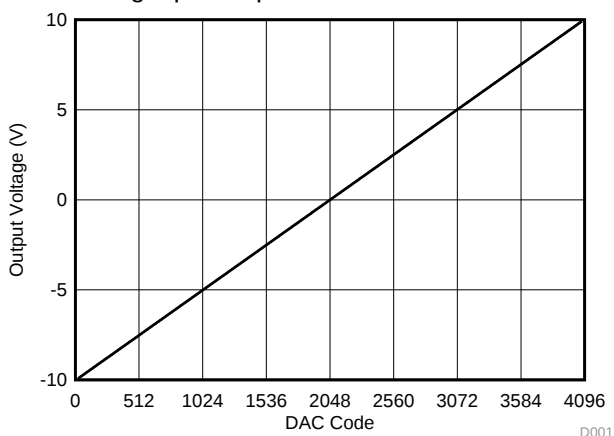


Figure 79. Bipolar Operation

10 Power Supply Recommendations

The DACx0508 operates within the specified V_{DD} supply range of 2.7 V to 5.5 V and V_{IO} supply range of 1.7 V to 5.5 V. The DACx0508 does not require specific supply sequencing.

The V_{DD} supply must be well-regulated and low-noise. Switching power supplies and dc/dc converters often have high frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high frequency spikes. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output. In order to further minimize noise from the power supply, include a 1- μ F to 10- μ F capacitor and 0.1- μ F bypass capacitor. The current consumption on the V_{DD} pin, the short-circuit current limit, and the load current for the device is listed in the [Electrical Characteristics](#). The power supply must meet the aforementioned current requirements.

11 Layout

11.1 Layout Guidelines

A precision analog component requires careful layout, the list below provides some insight into good layout practices.

- Bypass all power supply pins to ground with a low ESR ceramic bypass capacitor. The typical recommended bypass capacitance is 0.1- to 0.22- μ F ceramic with a X7R or NP0 dielectric.
- Place power supplies and REF bypass capacitors close to the pins to minimize inductance and optimize performance.
- Use a high-quality ceramic type NP0 or X7R for its optimal performance across temperature, and very low dissipation factor.
- The digital and analog sections must have proper placement with respect to the digital pins and analog pins of the DACx0508 device. The separation of analog and digital blocks minimizes coupling into neighboring blocks, as well as interaction between analog and digital return currents.

11.2 Layout Examples

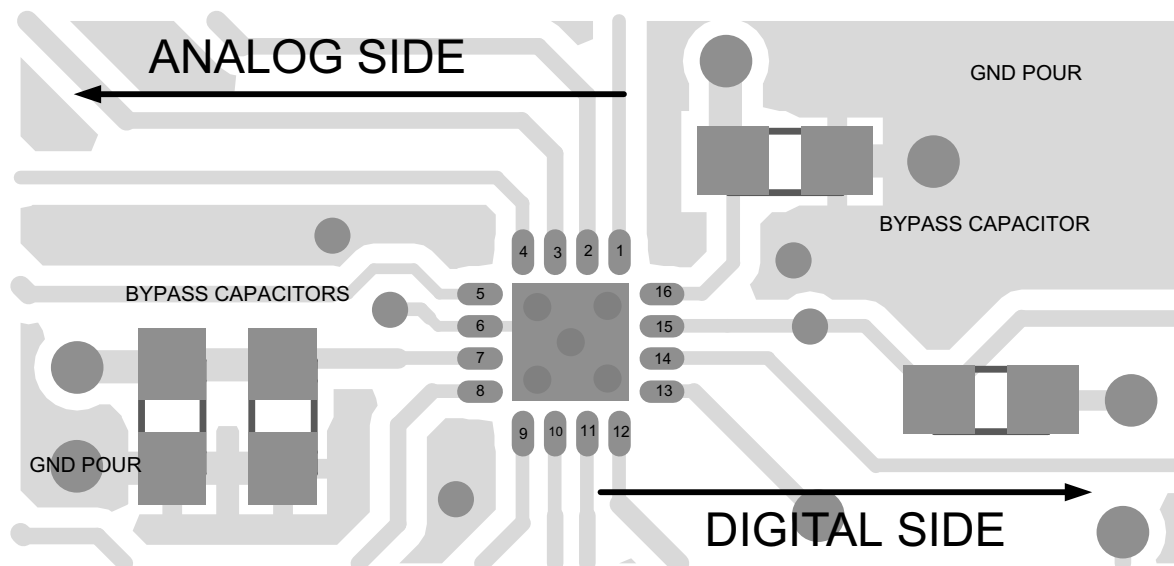


Figure 80. DACx0508 QFN Layout Example

Layout Examples (continued)

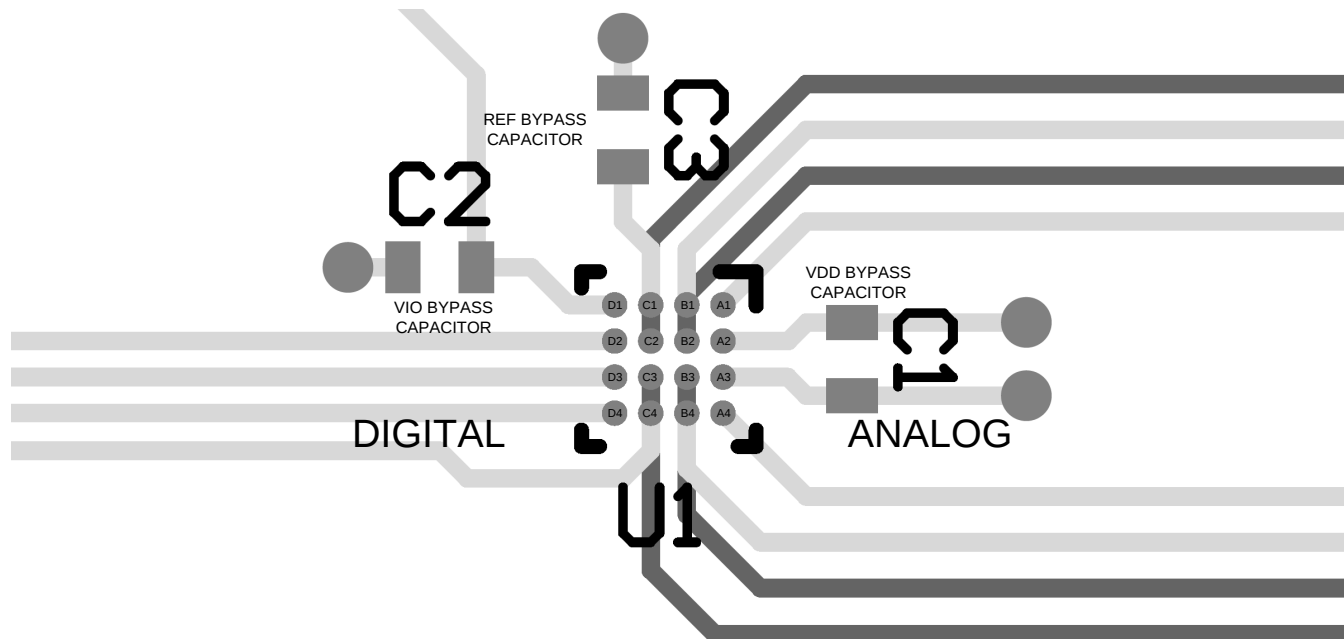


Figure 81. DACx0508 DSBGA Layout Example

12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 19. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
DAC80508	Click here	Click here	Click here	Click here	Click here
DAC70508	Click here	Click here	Click here	Click here	Click here
DAC60508	Click here	Click here	Click here	Click here	Click here

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DAC60508MCRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658MC
DAC60508MCRTER.A	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658MC
DAC60508MCRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658MC
DAC60508MCRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658MC
DAC60508MCRTET.A	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658MC
DAC60508MCRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658MC
DAC60508MCYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65MC
DAC60508MCYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65MC
DAC60508MCYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65MC
DAC60508MCYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65MC
DAC60508MRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658M
DAC60508MRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658M
DAC60508MRTERG4	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658M
DAC60508MRTERG4.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658M
DAC60508MRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658M
DAC60508MRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658M
DAC60508MYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65M
DAC60508MYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65M
DAC60508MYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65M
DAC60508MYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65M
DAC60508ZCRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658ZC
DAC60508ZCRTER.A	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658ZC
DAC60508ZCRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658ZC
DAC60508ZCRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658ZC
DAC60508ZCRTET.A	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658ZC
DAC60508ZCRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658ZC
DAC60508ZCYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65ZC
DAC60508ZCYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65ZC
DAC60508ZCYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65ZC

PACKAGE OPTION ADDENDUM

17-Jun-2025

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DAC60508ZCYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65ZC
DAC60508ZRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658Z
DAC60508ZRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658Z
DAC60508ZRTERG4	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658Z
DAC60508ZRTERG4.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658Z
DAC60508ZRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658Z
DAC60508ZRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	658Z
DAC60508ZYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65Z
DAC60508ZYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65Z
DAC60508ZYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65Z
DAC60508ZYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	65Z
DAC70508MRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758M
DAC70508MRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758M
DAC70508MRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758M
DAC70508MRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758M
DAC70508MYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75M
DAC70508MYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75M
DAC70508MYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75M
DAC70508MYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75M
DAC70508ZRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758Z
DAC70508ZRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758Z
DAC70508ZRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758Z
DAC70508ZRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758Z
DAC70508ZRTETG4	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758Z
DAC70508ZRTETG4.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	758Z
DAC70508ZYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75Z
DAC70508ZYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75Z
DAC70508ZYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75Z
DAC70508ZYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	75Z
DAC80508MCRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858MC
DAC80508MCRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858MC

PACKAGE OPTION ADDENDUM

17-Jun-2025

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DAC80508MCRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858MC
DAC80508MCRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858MC
DAC80508MCYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85MC
DAC80508MCYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85MC
DAC80508MCYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85MC
DAC80508MCYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85MC
DAC80508MRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858M
DAC80508MRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858M
DAC80508MRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858M
DAC80508MRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858M
DAC80508MRTETG4	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858M
DAC80508MRTETG4.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858M
DAC80508MYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85M
DAC80508MYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85M
DAC80508MYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85M
DAC80508MYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85M
DAC80508ZCRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858ZC
DAC80508ZCRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858ZC
DAC80508ZCRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858ZC
DAC80508ZCRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858ZC
DAC80508ZCYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85ZC
DAC80508ZCYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85ZC
DAC80508ZCYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85ZC
DAC80508ZCYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85ZC
DAC80508ZRTER	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858Z
DAC80508ZRTER.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858Z
DAC80508ZRTERG4	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858Z
DAC80508ZRTERG4.B	Active	Production	WQFN (RTE) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858Z
DAC80508ZRTET	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858Z
DAC80508ZRTET.B	Active	Production	WQFN (RTE) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	858Z
DAC80508ZYZFR	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85Z

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DAC80508ZYZFR.B	Active	Production	DSBGA (YZF) 16	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85Z
DAC80508ZYZFT	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85Z
DAC80508ZYZFT.B	Active	Production	DSBGA (YZF) 16	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	85Z

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

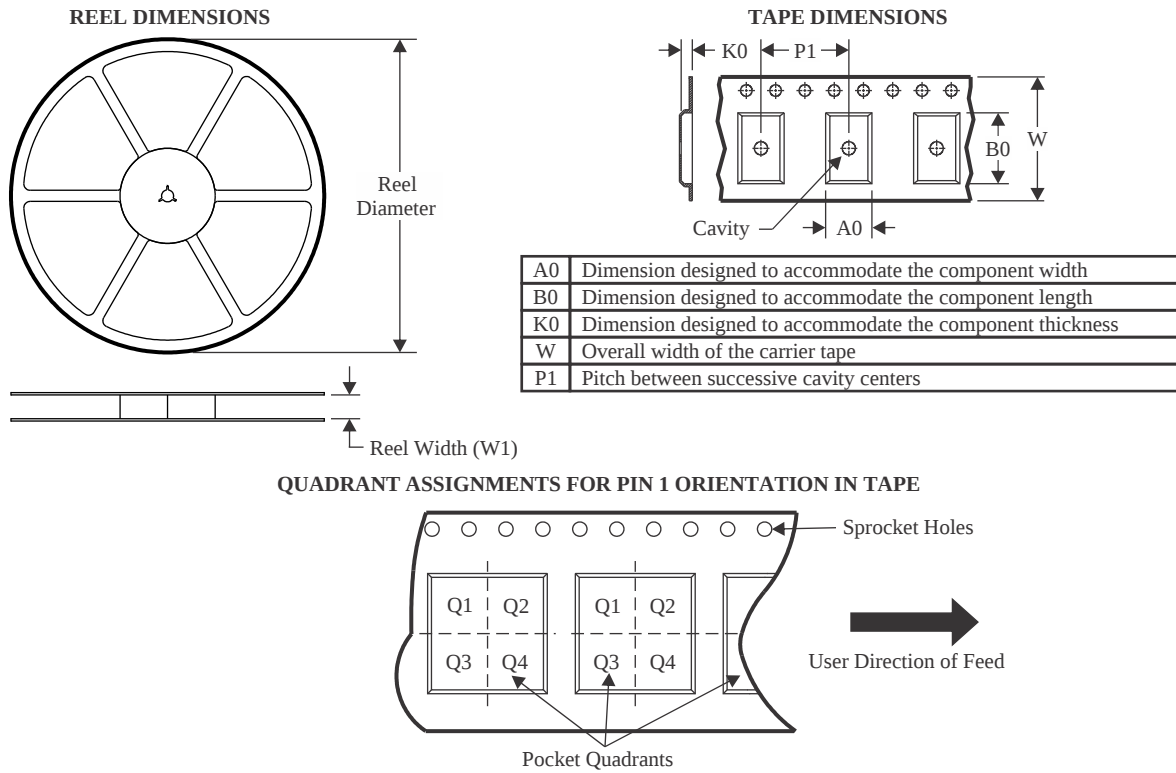
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

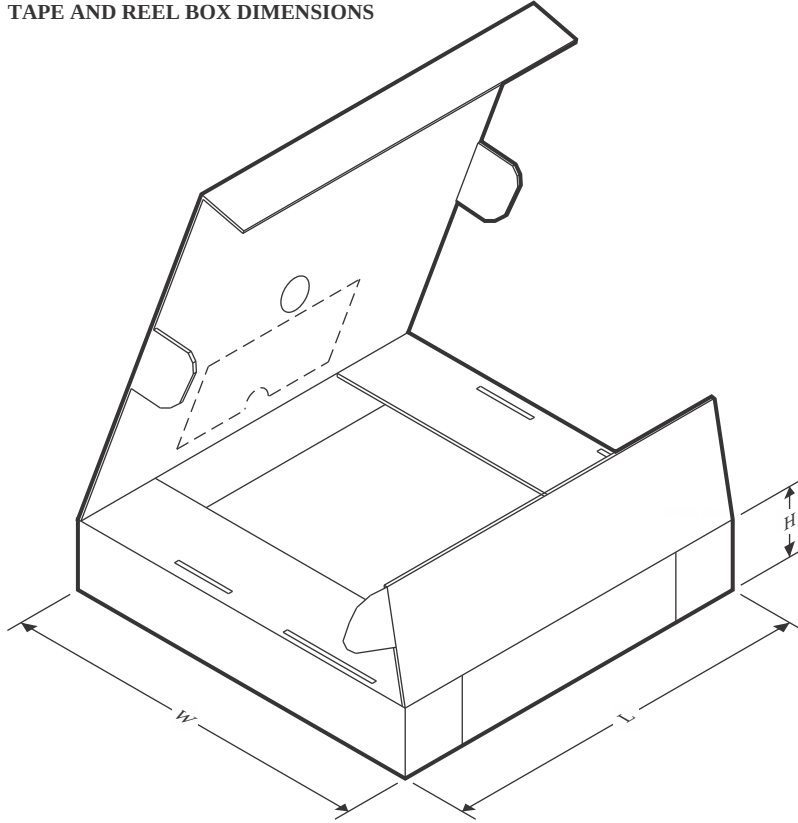
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC60508MCRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508MCRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508MCYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508MCYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508MRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508MRTERG4	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508MRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508MYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508MYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508ZCRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508ZCRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508ZCYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508ZCYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508ZRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508ZRTERG4	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC60508ZRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

18-Jun-2025

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC60508ZYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC60508ZYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC70508MRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC70508MRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC70508MYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC70508MYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC70508ZRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC70508ZRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC70508ZRTETG4	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC70508ZYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC70508ZYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508MCRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508MCRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508MCYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508MCYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508MRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508MRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508MRTETG4	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508MYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508MYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508ZCRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508ZCRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508ZCYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508ZCYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508ZRTER	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508ZRTERG4	WQFN	RTE	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508ZRTET	WQFN	RTE	16	250	180.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2
DAC80508ZYZFR	DSBGA	YZF	16	3000	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1
DAC80508ZYZFT	DSBGA	YZF	16	250	180.0	8.4	2.54	2.54	0.76	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC60508MCRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC60508MCRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC60508MCYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC60508MCYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC60508MRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC60508MRTERG4	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC60508MRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC60508MYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC60508MYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC60508ZCRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC60508ZCRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC60508ZCYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC60508ZCYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC60508ZRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC60508ZRTERG4	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC60508ZRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC60508ZYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC60508ZYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0

PACKAGE MATERIALS INFORMATION

18-Jun-2025

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC70508MRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC70508MRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC70508MYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC70508MYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC70508ZRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC70508ZRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC70508ZRTETG4	WQFN	RTE	16	250	213.0	191.0	35.0
DAC70508ZYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC70508ZYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC80508MCRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC80508MCRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC80508MCYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC80508MCYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC80508MRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC80508MRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC80508MRTETG4	WQFN	RTE	16	250	213.0	191.0	35.0
DAC80508MYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC80508MYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC80508ZCRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC80508ZCRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC80508ZCYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC80508ZCYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0
DAC80508ZRTER	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC80508ZRTERG4	WQFN	RTE	16	3000	367.0	367.0	38.0
DAC80508ZRTET	WQFN	RTE	16	250	213.0	191.0	35.0
DAC80508ZYZFR	DSBGA	YZF	16	3000	182.0	182.0	20.0
DAC80508ZYZFT	DSBGA	YZF	16	250	182.0	182.0	20.0

GENERIC PACKAGE VIEW

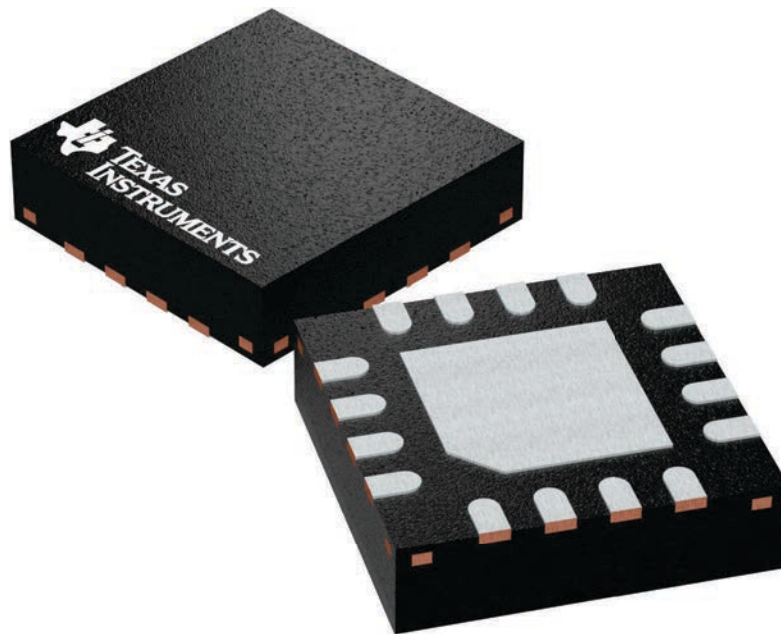
RTE 16

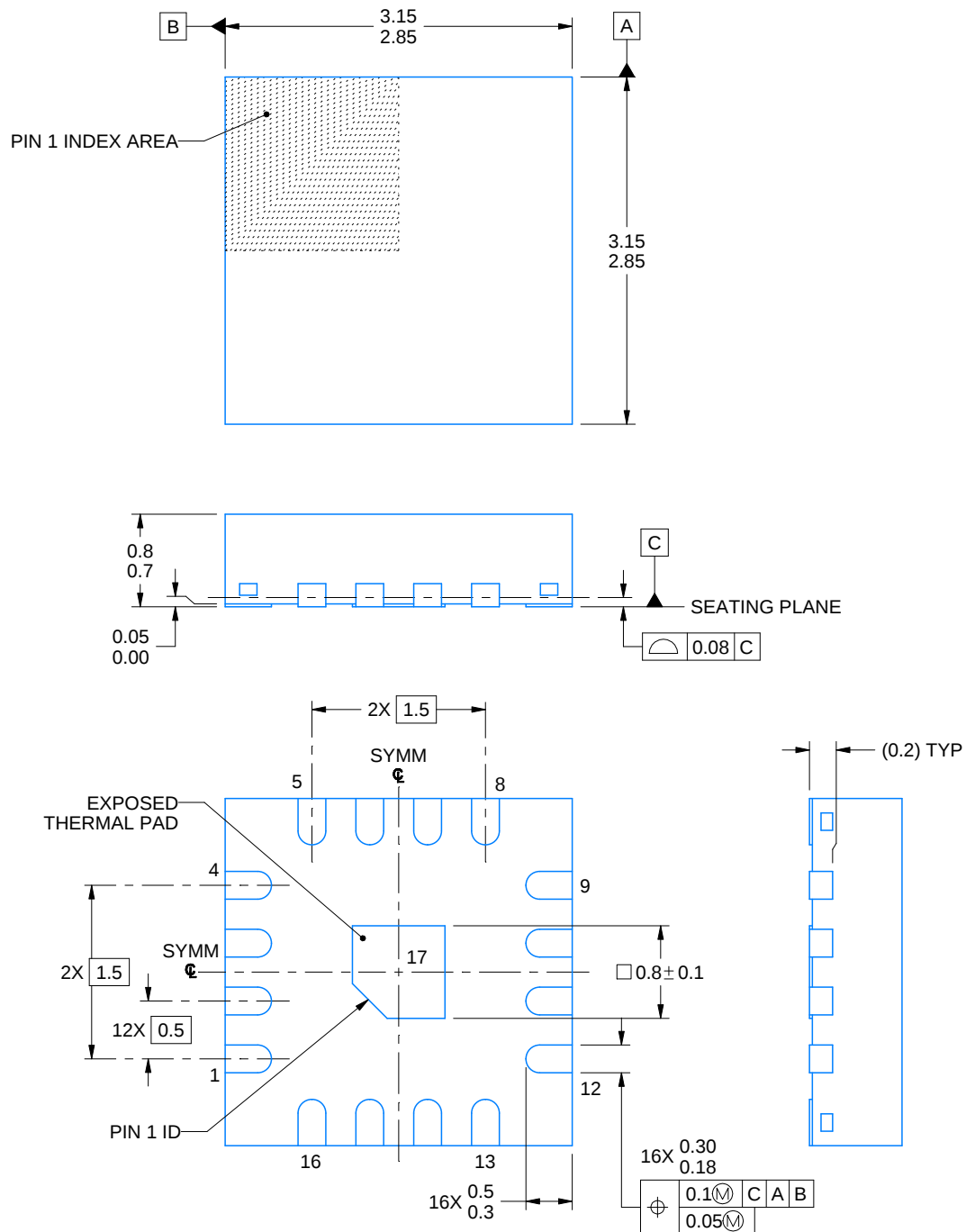
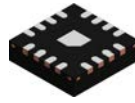
WQFN - 0.8 mm max height

3 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.





4219118/A 11/2018

NOTES:

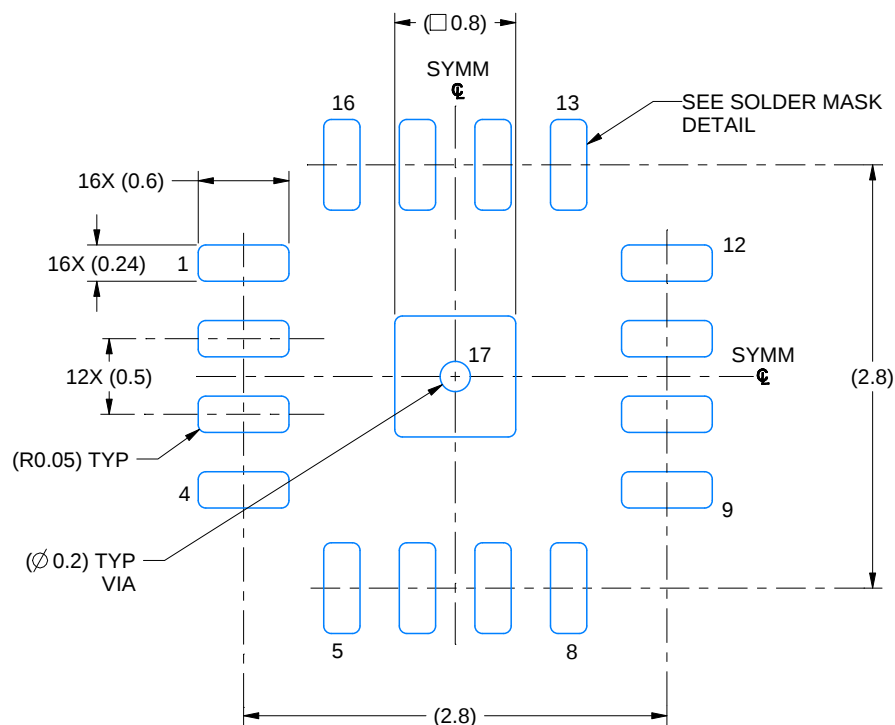
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RTE0016D

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



SOLDER MASK DETAILS

4219118/A 11/2018

NOTES: (continued)

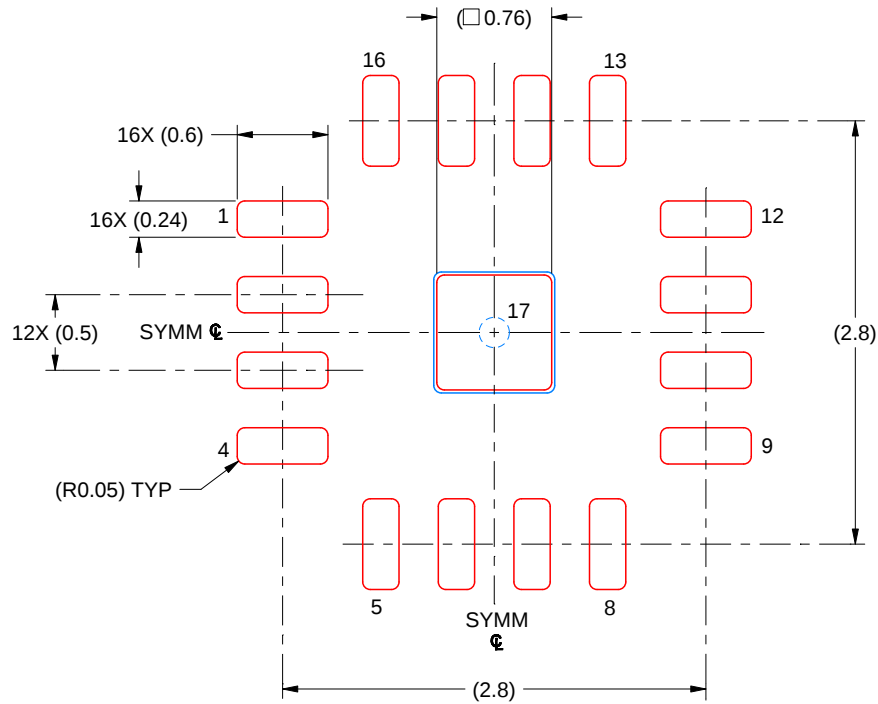
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RTE0016D

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 20X

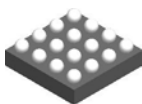
EXPOSED PAD 17
90% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

4219118/A 11/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

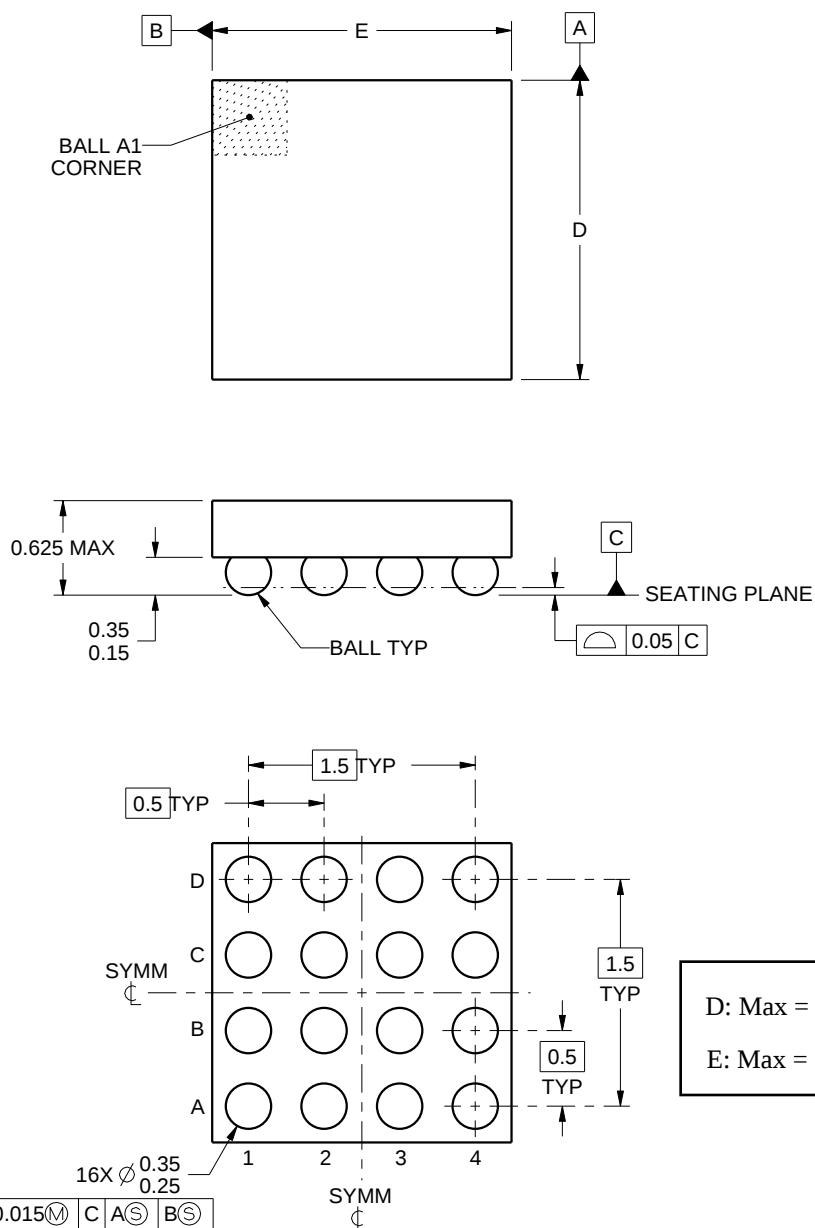
YZF0016



PACKAGE OUTLINE

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



4222182/A 08/2015

NOTES:

NanoFree is a trademark of Texas Instruments.

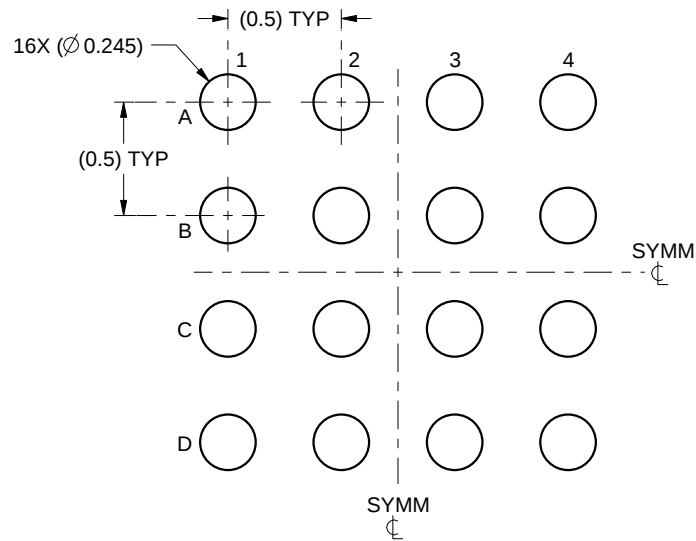
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

EXAMPLE BOARD LAYOUT

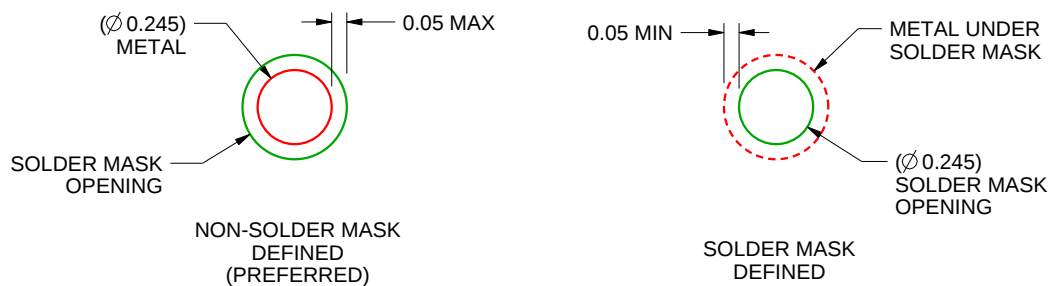
YZF0016

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:30X



SOLDER MASK DETAILS
NOT TO SCALE

4222182/A 08/2015

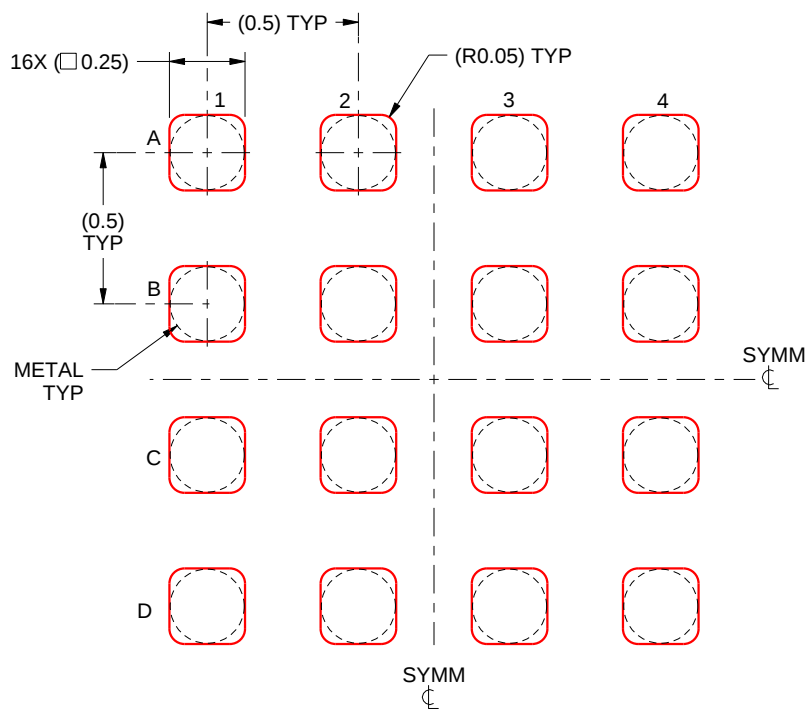
NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

YZF0016

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4222182/A 08/2015

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.